SIM7600E-H-R
Hardware Design

LTE Module

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1. Introduction

This document describes the electronic specifications, RF specifications, interfaces, mechanical characteristics and testing results of the SIMCom module. With the help of this document and other software application notes/user guides, users can understand and use module to design and develop applications quickly.

1.1 Product Outline

Aimed at the global market, the module support GSM, WCDMA, LTE-TDD and LTE-FDD. Users can choose the module according to the wireless network configuration. The supported radio frequency bands are described in the following table.

Table 1: Module frequency bands

Standard	Frequency bands
GSM	900MHz/1800M Hz
WCDMA	B1/B5/B8
LTE(TDD)	B41
LTE(FDD)	B1/B3/B5/B8/B20
GNSS	GPS/GLONASS/BeiDou

With a small physical dimension of 30*30*2.9 mm and with the functions integrated, the module can meet almost any space requirement in users' applications, such as smart phone, PDA, industrial handheld, machine-to-machine and vehicle application, etc.

1.2 Hardware Interface Overview

The interfaces are described in detail in the next chapters include:

● **Power Supply**
● **USB2.0 Interface**
● **UART Interface**
● **MMC/SD Interface**
● **SDIO Interface**

- **USIM Interface**
- **SPI Interface**
- **GPIO**
- **ADC**
- **LDO Power Output**
- **Current Sink Source**
- **PCM Interface**
- **I2C Interface**
- **HSIC Interface**
- **SGMII Interface**

1.3 Hardware Block Diagram

The block diagram of the module is shown in the figure below.
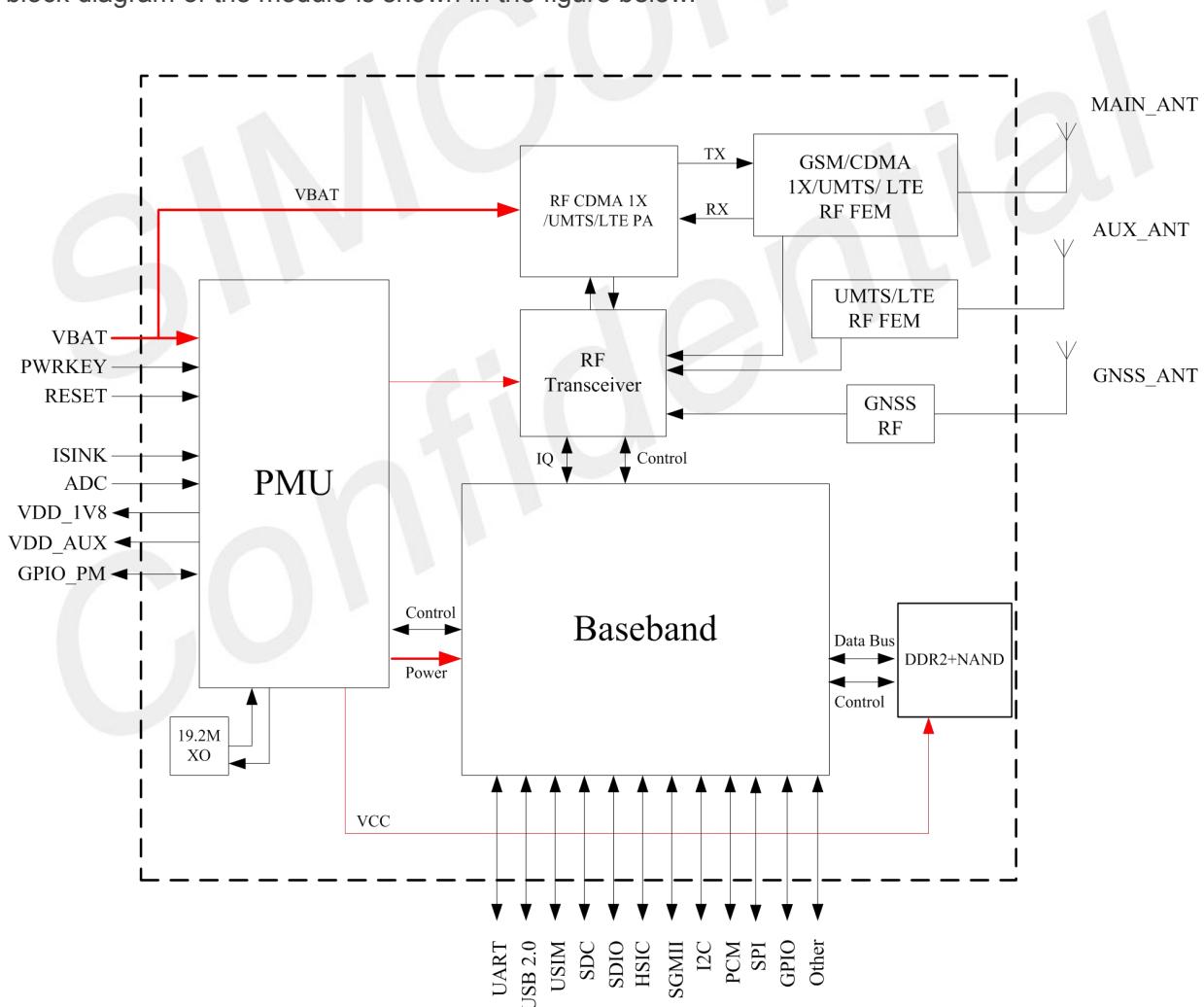
Figure 1: Module block diagram

1.4 Functional Overview

Table 2: General features

Feature	Implementation
Power supply	Single supply voltage 3.4~4.2V, Recommend supply voltage 3.8V
Power saving	Current in sleep mode : <5mA
Radio frequency bands	Please refer to the table 1
Transmitting power	GSM/GPRS power class: 　--GSM850: 4 (2W) 　--EGSM900: 4 (2W) 　--DCS1800: 1 (1W) 　--PCS1900: 1 (1W) EDGE power class: 　--GSM850: E2 (0.5W) 　--EGSM900: E2 (0.5W) 　--DCS1800: E1 (0.4W) 　--PCS1900: E1 (0.4W) UMTS power class: 　--WCDMA :3 (0.25W) LTE power class: 3 (0.25W)
Data Transmission Throughput	GPRS multi-slot class 12 EDGE multi-slot class 12 UMTS R99 speed: 384 kbps DL/UL HSPA+: 5.76 Mbps(UL), 42 Mbps(DL) HSDPA/HSUPA: 2.2 Mbps(UL), 2.8 Mbps(DL) LTE CAT 1: 10 Mbps(DL) 　　　　　5 Mbps(UL) LTE-FDD CAT4 ：150 Mbps (DL) , 50 Mbps (UL) LTE-TDD CAT4 ：130 Mbps (DL) , 35 Mbps (UL)
Antenna	GSM/UMTS/LTE main antenna. UMTS/LTE auxiliary antenna GNSS antenna
GNSS	GNSS engine (GPS,GLONASS and BD) Protocol: NMEA 0183
SMS	MT, MO, CB, Text and PDU mode SMS storage: USIM card or ME(default) Transmission of SMS alternatively over CS or PS.
USIM interface	Support identity card: 1.8V/ 3V
USIM application toolkit	Support SAT class 3, GSM 11.14 Release 98 Support USAT

Phonebook management	Support phonebook types: DC,MC,RC,SM,ME,FD,ON,LD,EN
Audio feature	Support PCM interface Only support PCM master mode and short frame sync, 16-bit linear data formats
UART interface	UART1 : A full modem serial port by default Baud rate: 300bps to 4Mbps(default:115200bps) Can be used as the AT commands or data stream channel Support RTS/CTS hardware handshake Multiplex ability according to GSM 07.10 Multiplexer Protocol UART2: Baud rate: 300bps to 4Mbps(default:115200bps) Can be used as the AT commands or Bluetooth data. Support RTS/CTS hardware handshake UART3: Can be used for printing kernel log UART4: Baud rate: 300bps to 4Mbps(default:115200bps) Can be used as the AT commands Support RTS/CTS hardware handshake
MMC/SD	Support MMC and SD cards with 2.85 V on SD port
SDIO	Support SDIO with 1.8 V only on SDIO port
USB	USB 2.0 high speed interface, Can used be send AT command, Software update, GNSS NMEA,USB voice function etc.
Firmware upgrade	Firmware upgrade over USB interface or FOTA
Physical characteristics	Size:30*30*2.9m Weight:5.7 g
Temperature range	Normal operation temperature: -30°C to +80°C Extended operation temperature: -40°C to +85°C* Storage temperature -45°C to +90°C

NOTE

Module is able to make and receive voice calls, data calls, SMS and make GPRS/UMTS/HSPA+/LTE traffic in -40℃ ~ +85℃. The performance will be reduced slightly from the 3GPP specifications if the temperature is outside the normal operating temperature range and still within the extreme operating temperature range.

2. Package Information

2.1 Pin Assignment Overview

All functions of the module will be provided through 143 pads that will be connected to the users' platform. The following Figure is a high-level view of the pin assignment of the module.
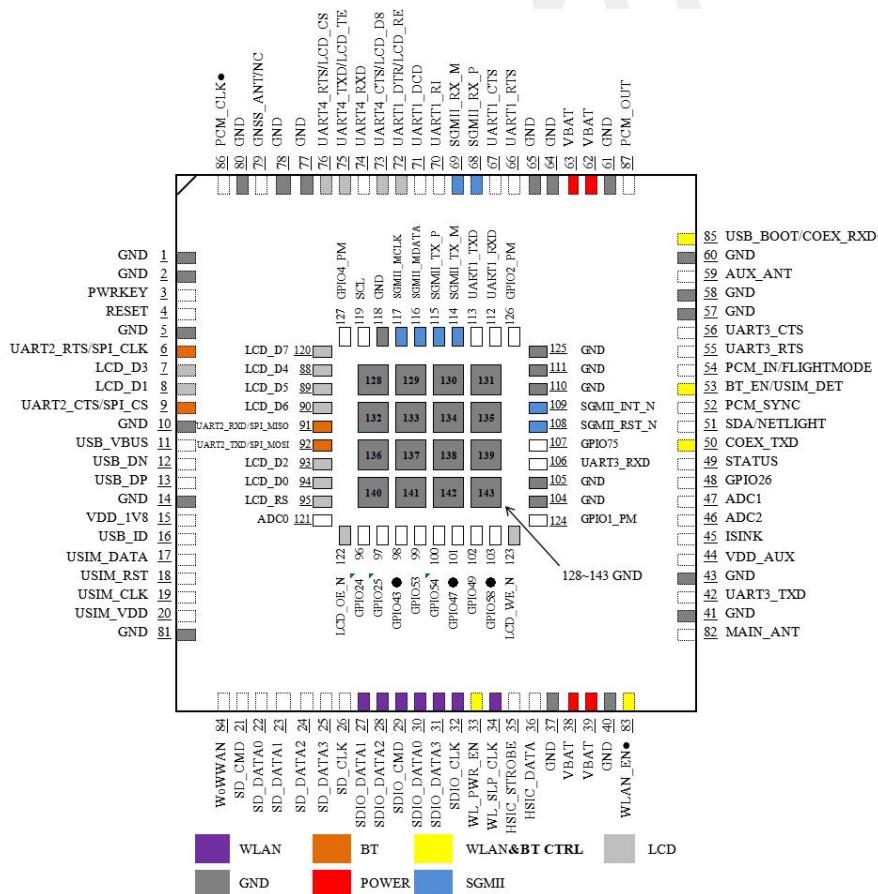
Figure 2: Pin assignment overview

Table 3: Pin definition

PIN No	PIN Name	PIN No	PIN Name
1	GND	2	GND
3	PWRKEY	4	RESET

5	GND	6	UART2 _RTS/SPI_CLK
7	LCD_D3	8	LCD_D1
9	UART2_CTS/SPI_CS	10	GND
11	USB_VBUS	12	USB_DN
13	USB_DP	14	GND
15	VDD_1V8	16	USB_ID
17	USIM_DATA	18	USIM_RST
19	USIM_CLK	20	USIM_VDD
21	SD_CMD	22	SD_DATA0
23	SD_DATA1	24	SD_DATA2
25	SD_DATA3	26	SD_CLK
27	SDIO_DATA1	28	SDIO_DATA2
29	SDIO_CMD	30	SDIO_DATA0
31	SDIO_DATA3	32	SDIO_CLK
33	WL_PWR_EN	34	WL_SLP_CLK
35	HSIC_STROBE	36	HSIC_DATA
37	GND	38	VBAT
39	VBAT	40	GND
41	GND	42	UART3_TXD
43	GND	44	VDD_AUX
45	ISINK	46	ADC2
47	ADC1	48	GPIO26
49	STATUS	50	COEX_TXD
51	SDA/NETLIGHT	52	PCM_SYNC
53	BT_EN/USIM_DET*	54	PCM_IN/FLIGHTMODE
55	UART3_RTS	56	UART3_CTS
57	GND	58	GND
59	AUX_ANT	60	GND
61	GND	62	VBAT
63	VBAT	64	GND
65	GND	66	UART1_RTS
67	UART1_CTS	68	SGMII_RX_P
69	SGMII_RX_M	70	UART1_RI
71	UART1_DCD	72	UART1_DTR/LCD_RESET*
73	UART4_CTS/LCD_D8*	74	UART4_RXD
75	UART4_TXD/LCD_TE*	76	UART4_RTS/LCD_CS*
77	GND	78	GND
79	GNSS_ANT/NC	80	GND
81	GND	82	MAIN_ANT
83	WLAN_EN●	84	WoWWAN
85	USB_BOOT/COEX_RXD●*	86	PCM_CLK●

87	PCM_OUT	88	LCD_D4
89	LCD_D5	90	LCD_D6
91	UART2_RXD/SPI_MISO	92	UART2_TXD/SPI_MOSI
93	LCD_D2	94	LCD_D0
95	LCD_RS	96	GPIO24
97	GPIO25	98	GPIO43●
99	GPIO53	100	GPIO54
101	GPIO47●	102	GPIO49
103	GPIO58●	104	GND
105	GND	106	UART3_RXD
107	GPIO75	108	SGMII_RST_N
109	SGMII_INT_N	110	GND
111	GND	112	UART1_RXD
113	UART1_TXD	114	SGMII_TX_M
115	SGMII_TX_P	116	SGMII_MDATA
117	SGMII_MCLK	118	GND
119	SCL	120	LCD_D7
121	ADC0	122	LCD_OE_N
123	LCD_WE_N	124	GPIO1_PM
125	GND	126	GPIO2_PM
127	GPIO4_PM	128~143	GND

NOTE

● Means before the normal power up, these pins cannot be pulled up; otherwise module will not be powered up normally.* Means that pins has a MUX function.

2.2 Pin Description

Table 4: IO parameters definition

Pin type	Description
PI	Power input
PO	Power output
AI	Analog input
AIO	Analog input/output
I/O	Bidirectional input /output
DI	Digital input
DO	Digital output
DOH	Digital output with high level

DOL	Digital output with low level
PU	Pull up
PD	Pull down

Table 5: Pin description

Pin name	Pin No	Default status		Description	Comment
		Domain	**IO**		
Power supply					
VBAT	38,39,62,63	-	PI	Power supply, voltage range: 3.4～4.2V.	
VDD_AUX	44	-	PO	LDO power output for other external circuits with Max 150mA current output. Its output voltage is 2.85V by default.（The voltage can be configured from 1.7V to 3.05V by AT command）.	If used SGMII function , this pin used for SGMII function. If unused, keep it open.
VDD_1V8	15	-	PO	1.8 output with Max 50mA current output for external circuit, such as level shift circuit.	If unused, keep it open.
GND	1,2,5,10,14,37,40,41,43,57,58,60,61,64,65,77,78,80,81,104,105,110,111,118,125,128~143	-	-	Ground	
System Control					
PWRKEY	3	-	DI,PU	System power on/off control input, active low.	The high voltage is 0.8V;
RESET	4	-	DI,PU	System reset control input, active low.	RESET has been pulled up to 1.8V via 40Kohm resistor internally.
SDC Interface					
SD_CMD	21	P2	I/O,PD	SDIO command	If unused, keep them open.
SD_DATA0	22	P2	I/O,PD	SDIO data	
SD_DATA1	23	P2	I/O,PD		

SD_DATA2	24	P2	I/O,PD	
SD_DATA3	25	P2	I/O,PD	
SD_CLK	26	P2	DO	SDIO clock

USIM Interface

USIM_DATA	17	P5	I/O,PU	USIM Card data I/O, which has been pulled up via a 10KR resistor to USIM_VDD internally. Do not pull it up or down externally.
USIM_RST	18	P5	DO, PD	USIM Reset
USIM_CLK	19	P5	DO, PD	USIM clock
USIM_VDD	20	-	PO	Power output for USIM card, its output Voltage depends on USIM card type automatically. Its output current is up to 50mA.

SGMII Interface

SGMII_RST_N	108	P6	DO	PHY Reset
SGMII_INT_N	109	P3	DI	PHY Int
SGMII_RX_P	68	-	AI	SGMII Bus receive data positive
SGMII_RX_M	69	-	AI	SGMII Bus receive data minus
SGMII_TX_M	114	-	AO	SGMII Bus transmit Data positive
SGMII_TX_P	115	-	AO	SGMII Bus transmit Data minus
SGMII_MDATA	116	P6	I/O	SGMII control data
SGMII_MCLK	117	P6	DO	SGMII control clock

USB Interface

USB_VBUS	11	-	AI	USB insert detect（3.0~5.25V）
USB_DN	12	-	AI,AO	USB data minus
USB_DP	13	-	AI,AO	USB data positive
USB_ID	16	-	AI	USB ID	It must be kept pen。If customer use OTG function, Please refer to "*SIM7600 Series EMMC-Reference Design*" and "*SIM7600 USB-OTG Application Note*"

Full function UART1

UART1_RTS	66	P3	DOH	Request to send	If unused, keep them open.
UART1_CTS	67	P3	DI	Clear to Send	
UART1_RXD	112	P3	DI	Receive Data	
UART1_RI	70	P3	DOH	Ring Indicator	
UART1_DCD	71	P3	DOH	Carrier detects	
UART1_TXD	113	P3	DOH	Transmit Data	
UART1_DTR/LCD _RESET	72	P3	DI,PU	DTE get ready/ LCD_RESET signal	

UART2 (Bluetooth data, can be configured to SPI interface)

UART2_RTS/SPI_ CLK	6	P3	DOH	Request to send /SPI bus clock	Bluetooth data interface.
UART2_RXD/SPI_ MISO	91	P3	DI	Receive Data /SPI bus master input slave output	
UART2_TXD/SPI_ MOSI	92	P3	DOH	Transmit Data /SPI bus master output slave input	
UART2_CTS/SPI_ CS	9	P3	DI	Clear to Send /SPI bus chip select	

UART3 (Debug log)

UART3_TXD	42	P3	DOH	Log output.	Only log function.
UART3_RXD	106	P3	DI	Log input.	

UART4

UART4_CTS/LCD _D8	73	P3	DI	Clear to Send/ LCD bus data8	
UART4_RTS/LCD _CS	**76**	P3	DO	Request to send/ LCD bus chip select	
UART4_TXD/LCD _TE	75	P3	DO	Transmit Data/ LCD bus chip/ select (tearing)	
UART4_RXD	74	P3	DI	Receive Data	

I2C

SCL	119	P3	OD	I2C clock output	If unused, keep open, or else pull them up via 2.2KΩ resistors to 1.8V.
SDA/NETLIGHT	51	P3	OD	I2C data input/output	

SDIO Interface

SDIO_DATA1	27	P3	I/O	SDIO bus data1	It can be used for WLAN function. If unused, please keep them open.
SDIO_DATA2	28	P3	I/O	SDIO bus data2	
SDIO_CMD	29	P3	I/O	SDIO bus command	
SDIO_DATA0	30	P3	I/O	SDIO bus data0	
SDIO_DATA3	31	P3	I/O	SDIO bus data3	
SDIO_CLK	32	P3	DO	SDIO bus clock	

HSIC Interface

| HSIC_STROBE | 35 | P8 | I/O | HSIC strobe | If use, please refer to *document [27]* Otherwise please keep them open. |
| HSIC_DATA | 36 | P8 | I/O | HSIC data | |

9bit LCD Interface					
LCD_D4	88	P3	DO	LCD bus data bit4	
LCD_D5	89	P3	DO	LCD bus data bit5	
LCD_D6	90	P3	DO	LCD bus data bit6	
LCD_D3	7	P3	DO	LCD bus data bit3	
LCD_D1	8	P3	DO	LCD bus data bit1	
LCD_D2	93	P3	DO	LCD bus data bit2	
LCD_D0	94	P3	DO	LCD bus data bit0	
LCD_D7	120	P3	DO	LCD bus data bit7	
UART4_CTS/LCD_D8	73	P3	DO	LCD bus data bit8	If unused, please keep them open.
LCD_RS	95	P3	DO	LCD bus data/command	
LCD_OE_N	122	P3	DO	LCD bus host read	
LCD_WE_N	123	P3	DO	LCD host write	
UART1_DTR/LCD_RESET	72	P3	DO	LCD bus reset	
UART4_RTS/LCD_CS	76	P3	DO	LCD bus chip select	
UART4_TXD/LCD_TE	75	P3	DO	LCD bus chip select (tearing)	

PCM Interface					
PCM_OUT	87	P3	DO,PD	PCM data output.	If unused, please keep them open.
PCM_IN/FLIGHTMODE	54	P3	DI,PD	PCM data input.	
PCM_SYNC	52	P3	I/O,PD	PCM data frame sync signal.	
PCM_CLK●	86	P3	I/O,PU	PCM data bit clock.	

GPIO					
STATUS	49	P3	DO,PU	Operating status output. High level: Power on and firmware ready Low level: Power off	If unused, please keep them open.
GPIO26	48	P3	IO,PD	Default: GPIO SD card insertion detect(option) H: SD card is removed L: SD card is inserted	
GPIO24	96	P3	IO,PD	Default: GPIO	
GPIO25	97	P3	IO,PD	Default: GPIO	
GPIO43●	98	P3	IO,PD	Default: GPIO	
GPIO53	99	P3	IO,PD	Default: GPIO	
GPIO54	100	P3	IO,PD	Default: GPIO	
GPIO47●	101	P3	IO,PD	Default: GPIO	
GPIO49	102	P3	IO,PD	Default: GPIO	
GPIO58●	103	P3	IO,PD	Default: GPIO	
GPIO75	107	P3	IO,PD	Default: GPIO	
GPIO19	119	P3	IO,PD	Default: GPIO	

GPIO1_PM	124	P3	IO,PD	Default: GPIO	
GPIO2_PM	126	P3	IO,PD	Default: GPIO	
GPIO4_PM	127	P3	IO,PD	Default: GPIO	
Antenna					
MAIN_ANT	82	-	AIO	MAIN antenna soldering pad	
AUX_ANT	59	-	AI	Auxiliary antenna soldering pad	
GNSS_ANT	79	-	AI	GNSS antenna soldering pad	
Others					
ISINK	45	-	PI	Ground-referenced current sink.	
ADC1	47	-	AI	Analog-digital converter input 1	If unused, please keep them open.
ADC2	46	-	AI	Analog-digital converter input 2	
ADC0	121	-	AI	Analog-digital converter input 0	
WL_PWR_EN	33	P3	DO，PU	WIFI power enable	If unused, please keep them open.
WL_SLP_CLK	34	P3	AO	WIFI sleep clock	
COEX_TXD	50	P3	DI	Wi-Fi/BT coexistence engine; LTE/BT coexistence.	
WLAN_EN●	83	P3	I/O	WIFI enable	
WoWWAN	84	P3	I/O	-	
USB_BOOT/COEX_RXD●	85	P3	DI	If pulled up to 1.8V before power on, then the module would enter in download mode. WIFI version: Wi-Fi/BT coexistence engine; LTE/BT coexistence.	Do place 2 test points for debug. Do not pull up USB_BOOT during normal power up!
BT_EN/USIM_DET	53	P3	DI,PU	WIFI version: Bluetooth enable.	

2.3 Mechanical Information

The following figure shows the package outline drawing of module.
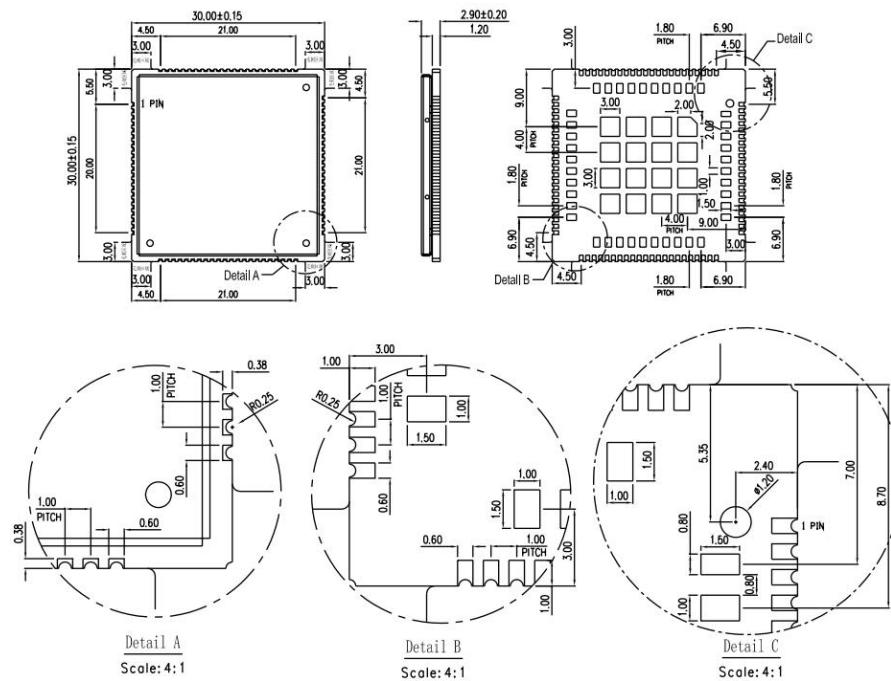
Figure 3: Dimensions (Unit: mm)

2.4 Footprint Recommendation
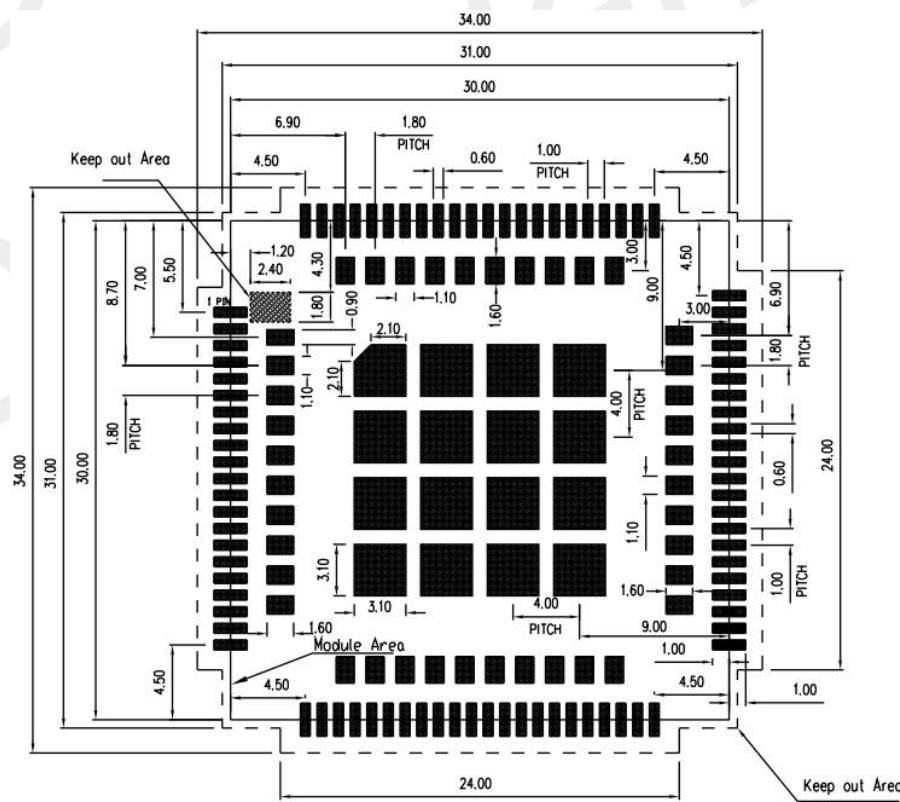
Figure 4: Footprint recommendation (Unit: mm)

3. Interface Application

3.1 Power Supply

The power supply pins of module include 4 pins (pin 62&63, pin 38&39) named VBAT. The 4 VBAT pads supply the power to RF and baseband circuits directly. On VBAT pads, the ripple current up to 2A typically, due to GSM/GPRS emission burst (every 4.615ms), may cause voltage drop. So the power supply for these pads must be able to provide sufficient current up to more than 2A in order to avoid the voltage drop is more than 300mV. The following figure shows the VBAT voltage ripple wave at the maximum power transmit phase.
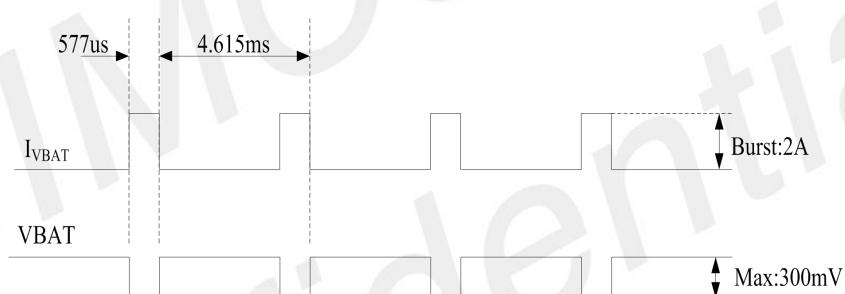
Figure 5: VBAT voltage drop during burst emission (GSM/GPRS)

NOTE

The test condition: The voltage of power supply for VBAT is 3.8V, Cd=100 µF tantalum capacitor (ESR=0.7Ω) and Cf=100nF (Please refer to Figure 6—Application circuit).

Table 6: VBAT pins electronic characteristic

Symbol	Description	Min.	Typ.	Max.	Unit
VBAT	Module power voltage	3.4	3.8	4.2	V
I$_{VBAT(peak)}$	Module power peak current in normal mode.	-	-	2	A
I$_{VBAT(average)}$	Module power average current in normal mode	Please refer to the table 38			
I$_{VBAT(sleep)}$	Power supply current in sleep mode				
I$_{VBAT(power-off)}$	Module power current in power off mode.	-	-	20	uA

3.1.1 Power Supply Design Guide

Make sure that the voltage on the VBAT pins will never drop below 3.4V, even during a transmit burst, when current consumption may rise up to 2A. If the voltage drops below 3.4V, the RF performance may be affected.

NOTE

If the power supply for VBAT pins can support up to 2A, more than 300uF capacitors are recommended .Otherwise users must use a total of 1000uF capacitors typically, in order to avoid of the voltage drop more than 300mV.

Some multi-layer ceramic chip (MLCC) capacitors (0.1/1uF) with low ESR in high frequency band can be used for EMC.

These capacitors should be put as close as possible to VBAT pads. Also, users should keep VBAT trace on circuit board wider than 2 mm to minimize PCB trace impedance. The following figure shows the recommended circuit.

Recommend Bead for VBAT filter are BLM21PG300SN1D and MPZ2012S221A。
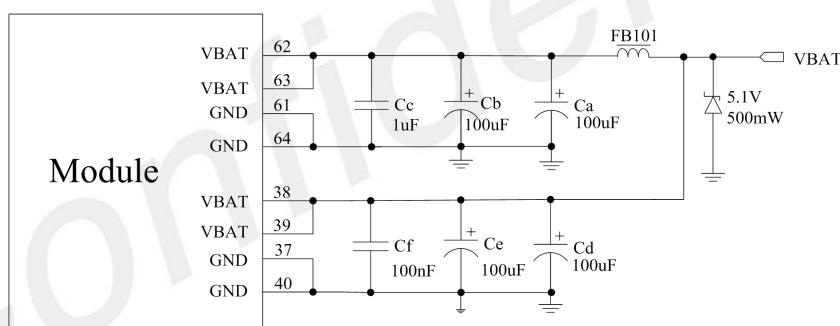
Figure 6: Power supply application circuit

NOTE

1. In order to guard for over voltage protection, it is suggested to use TVS.
2. User could only power pin 62, 63 or only power pin 38, 39, for these pins are connected inside the module.

Table 7: Recommended TVS list

No.	Manufacturer	Part Number	Power dissipation	Package
1	JCET	ESDBW5V0A1	5V	DFN1006-2L
2	WAYON	WS05DPF-B	5V	DFN1006-2L
3	WILLSEMI	ESD5611N	5V	DFN1006-2L
4	WILLSEMI	ESD56151W05	5V	SOD-323
5*	PRISEMI	PESDHC2FD4V5BH	4.5V	DFN1006-2L
6*	WAYON	WS4.5DPV	4.5V	DFN1610-2L

NOTE

1. If user chooses TVS, please pay attention to Clamping Voltage in datasheet. For example when the surge input is 100V,the Clamping Voltage is less than 10V.
2. VBAT is higher than 3.8V, do not choose 5 and 6.

3.1.2   Recommended Power Supply Circuit

It is recommended that a switching mode power supply or a linear regulator power supply is used. It is important to make sure that all the components used in the power supply circuit can resist a peak current up to 2A.The following figure shows the linear regulator reference circuit with 5V input and 3.8V output.
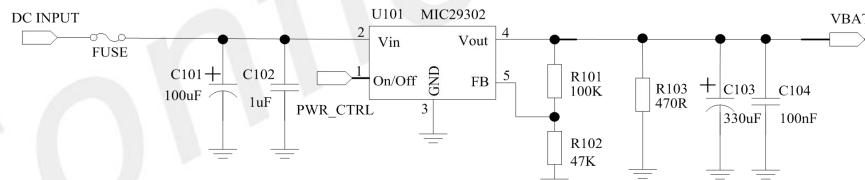
Figure 7: Linear regulator reference circuit

If there is a big voltage difference between input and output for VBAT power supply, or the efficiency is extremely important, then a switching mode power supply will be preferable. The following figure shows the switching mode power supply reference circuit.
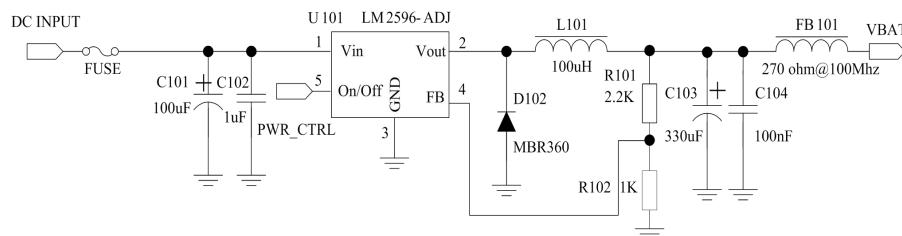
Figure 8: Switching mode power supply reference circuit

NOTE

The Switching Mode power supply solution for VBAT must be chosen carefully against Electro Magnetic Interference and ripple current from depraving RF performance.

3.1.3 Voltage Monitor

To monitor the VBAT voltage, the AT command "AT+CBC" can be used.For monitoring the VBAT voltage outside or within a special range, the AT command "AT+CVALARM" can be used to enable the under-voltage warning function.If users need to power off module, when the VBAT voltage is out of a range, the AT command "AT+CPMVT" can be used to enable under-voltage power-off function.

NOTE

Under-voltage warning function and under-voltage power-off function are disabled by default. For more information about these AT commands, please refer to Document [1].

3.2 Power on/Power off/Reset Function

3.2.1 Power on

Module can be powered on by pulling the PWRKEY pin down to ground. The PWRKEY pin has been pulled up with a diode to 1.8V internally, so it does not need to be pulled up externally. It is strongly recommended to put a100nF capacitor, an ESD protection diode, close to the PWRKEY pin as it would strongly enhance the ESD performance of PWRKEY pin. Please refer to the following figure for the recommended reference circuit.
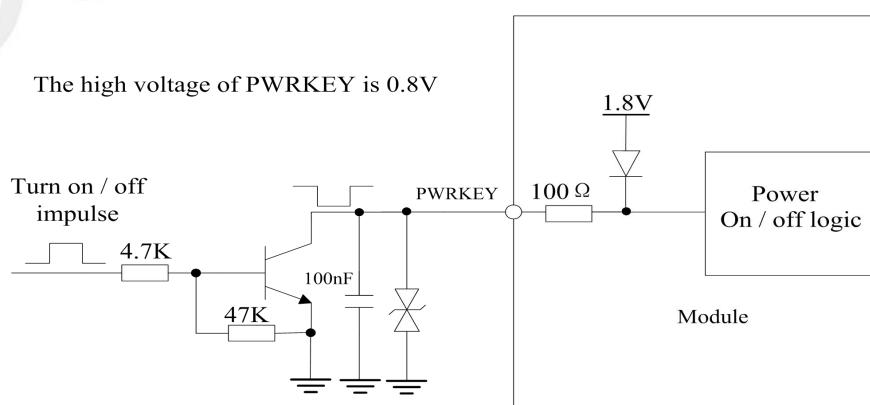
Figure 9: Reference power on/off circuit

> **NOTE**
>
> Module could be automatically power on by connecting PWRKEY pin to ground via 0R resistor directly.

The power-on scenarios are illustrated in the following figure.
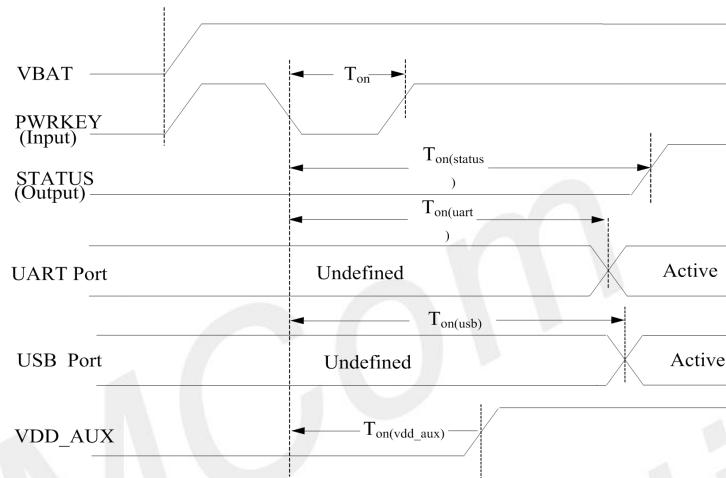
Figure 10: Power on timing sequence

Table 8: Power on timing and electronic characteristic

Symbol	Parameter	Min.	Typ.	Max.	Unit
T_{on}	The time of active low level impulse of PWRKEY pin to power on module	100	500	-	ms
$T_{on(status)}$	The time from power-on issue to STATUS pin output high level(indicating power up ready)	15	16	-	s
$T_{on(uart)}$	The time from power-on issue to UART port ready	13	14	-	s
$T_{on(vdd\_aux)}$	The time from power-on issue to VDD_AUX ready		2.5	-	s
$T_{on(usb)}$	The time from power-on issue to USB port ready	11	12	-	s
V_{IH}	Input high level voltage on PWRKEY pin	0.6	0.8	1.8	V
V_{IL}	Input low level voltage on PWRKEY pin	-0.3	0	0.5	V

3.2.2 Power off

The following methods can be used to power off module.

- Method 1: Power off module by pulling the PWRKEY pin down to ground.
- Method 2: Power off module by AT command "AT+CPOF".
- Method 3: over-voltage or under-voltage automatic power off. The voltage range can be set by AT command "AT+CPMVT".

● Method 4: over-temperature or under-temperature automatic power off.

<div style="border:1px solid #ccc;">

NOTE

1. If the temperature is outside the range of -30~+80℃, some warning will be reported via AT port. If the temperature is outside the range of -40~+85℃, module will be powered off automatically.
2. For details about "AT+CPOF" and "AT+CPMVT", please refer to Document [1].

</div>

These procedures will make module disconnect from the network and allow the software to enter a safe state, and save data before module be powered off completely. The power off scenario by pulling down the PWRKEY pin is illustrated in the following figure.
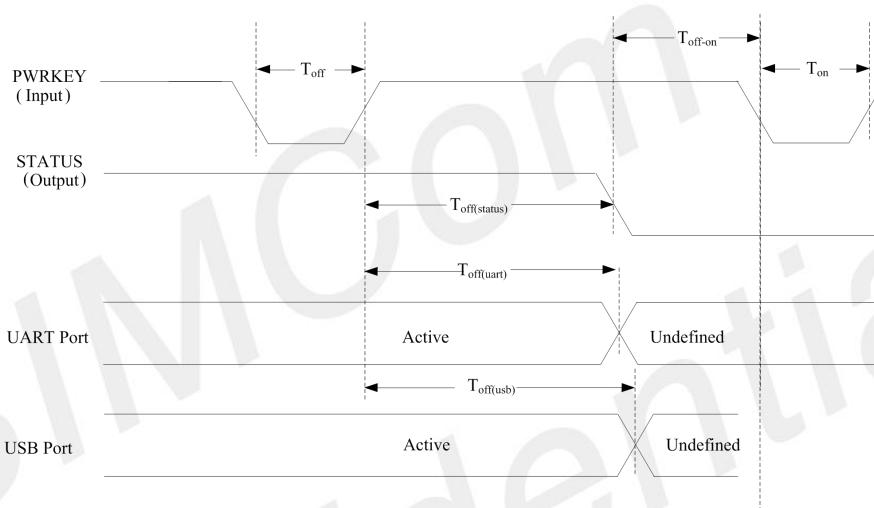
Figure 11: Power off timing sequence

Table 9: Power off timing and electronic characteristic

Symbol	Parameter	Time value			Unit
		Min.	Typ.	Max.	
T_{off}	The active low level time pulse on PWRKEY pin to power off module	--	2.5	--	s
$T_{off(status)}$	The time from power-off issue to STATUS pin output low level(indicating power off)*	25	26	-	s
$T_{off(uart)}$	The time from power-off issue to UART port off	14	15	-	s
$T_{off(usb)}$	The time from power-off issue to USB port off	27	28	-	s
T_{off-on}	The buffer time from power-off issue to power-on issue	0	-	-	s

<div style="border:1px solid #ccc;">

NOTE

The STATUS pin can be used to detect whether module is powered on or not. When module has been powered on and firmware goes ready, STATUS will be high level, or else STATUS will still low level.

</div>

3.2.3   Reset Function

Module can be reset by pulling the RESET pin down to ground.

> **NOTE**
>
> This function is only used as an emergency reset, when AT command "AT+CPOF" and the PWRKEY pin all have lost efficacy.

The RESET pin has been pulled up with a 40KΩ resistor to 1.8V internally, so it does not need to be pulled up externally. It is strongly recommended to put a100nF capacitor and an ESD protection diode close to the RESET pin. Please refer to the following figure for the recommended reference circuit.
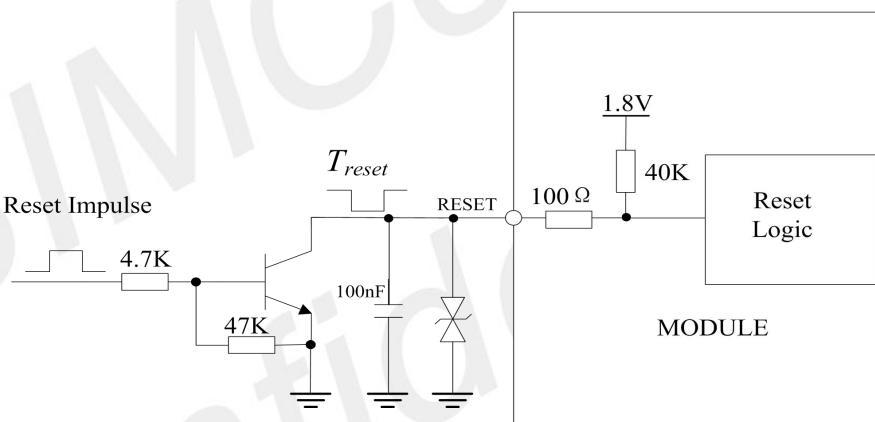
Figure 12: Reference reset circuit

Table 10: RESET pin electronic characteristic

Symbol	Description	Min.	Typ.	Max.	Unit
T_{reset}	The active low level time impulse on RESET pin to reset module	100	200	500	ms
V_{IH}	Input high level voltage	1.17	1.8	2.1	V
V_{IL}	Input low level voltage	-0.3	0	0.8	V

3.3 UART Interface

Module provides 4 UART (universal asynchronous serial transmission) interface as DCE (Data Communication Equipment). AT commands and data transmission can be performed through UART interface.

3.3.1 UART Design Guide

The following figures show the reference design.
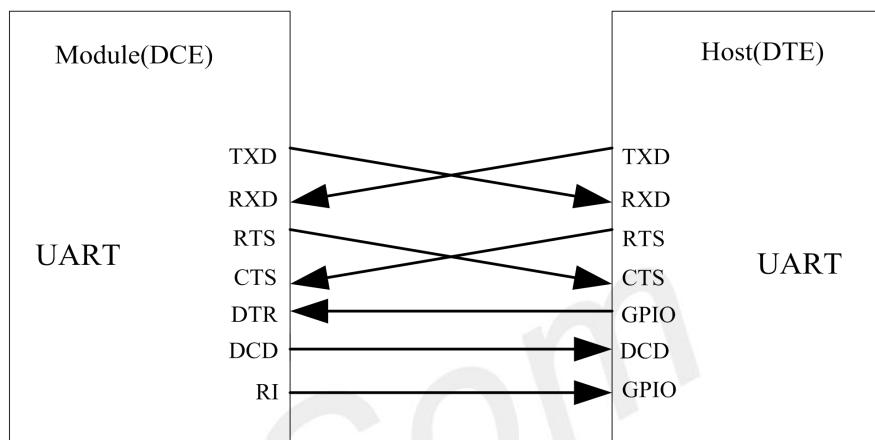
Figure 13: UART full modem
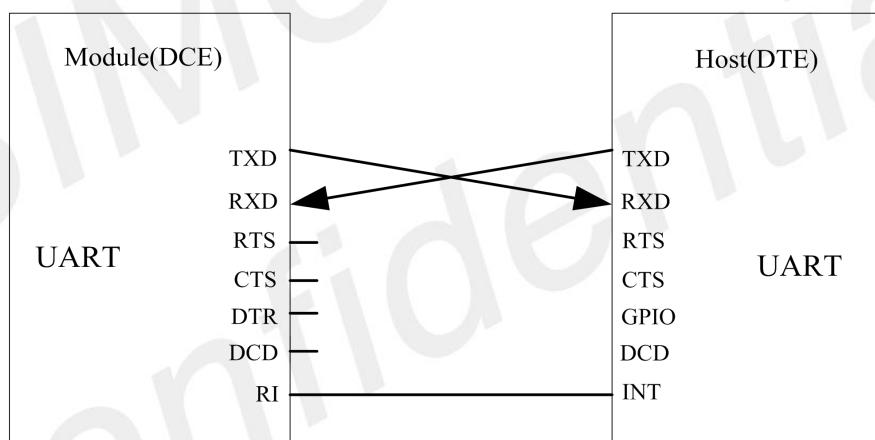
Figure 14: UART null modem

The module UART is 1.8V voltage interface. If user's UART application circuit is 3.3V voltage interface, the level shifter circuits should be used for voltage matching. The TXB0108RGYR provided by Texas Instruments is recommended. The following figure shows the voltage matching reference design.
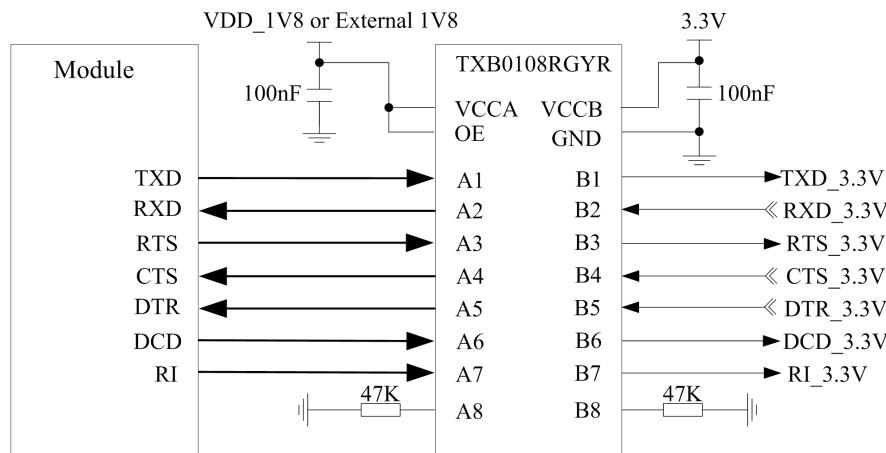
Figure 15: Reference circuit of level shift

User can use another level shifter circuits as follow.
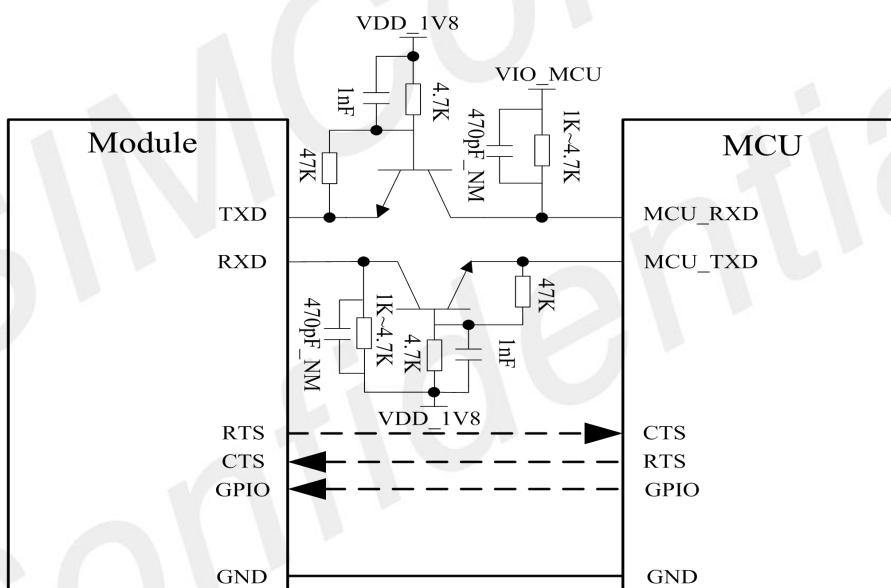
Figure 16: level matching circuit

To comply with RS-232-C protocol, the RS-232-C level shifter chip should be used to connect module to the RS-232-C interface, for example SP3238ECA, etc.

NOTE

1. User need to use high speed transistors such as MMBT3904.
2. Module supports the following baud rates: 300, 600, 1200, 2400, 4800, 9600, 19200, 38400, 57600, 115200, 230400, 460800, 921600, 3200000, 3686400, 4000000bps. The default band rate is 115200bps.

3.3.2   RI and DTR Behavior

The RI pin can be used to interrupt output signal to inform the host controller such as application CPU. Normally RI will keep high level until certain conditions such as receiving SMS, or a URC report coming, and then it will change to low level.
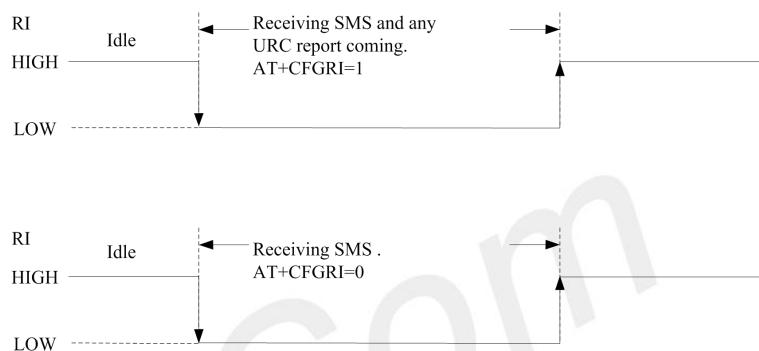
Figure 17: RI behaviour（SMS and URC report）

Normally RI will be kept at a high level until a voice call, then it will output periodic rectangular wave with 5900ms low level and 100ms high level. It will output this kind of periodic rectangular wave until the call is answered or hung up.
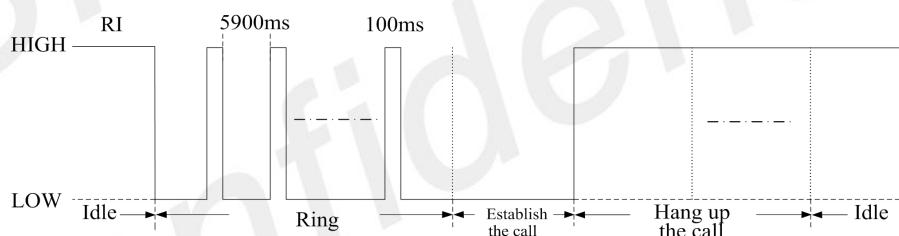
Figure 18: RI behaviour（voice call）

NOTE

For more details of AT commands about UART, please refer to document [1] and [22].

DTR pin can be used to wake module from sleep. When module enters sleep mode, pulling down DTR can wake module.

3.4 USB Interface

The module contains a USB interface compliant with the USB2.0 specification as a peripheral, but the USB charging function is not supported.

3.4.1. USB diagram

Module can be used as a USB device. module supports the USB suspend and resume mechanism which can reduce power consumption. If there is no data transmission on the USB bus, module will enter suspend mode automatically, and will be resumed by some events such as voice call, receiving SMS, etc.
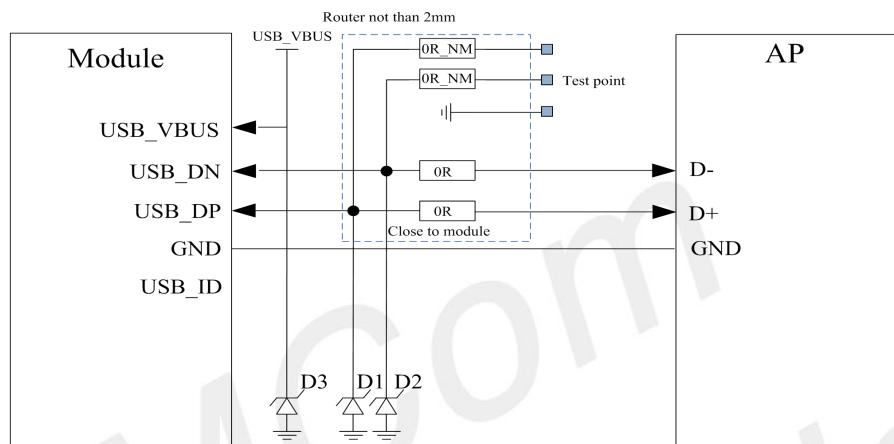
Figure 19: USB reference circuit

Because of the high bit rate on USB bus, more attention should be paid to the influence of the junction capacitance of the ESD component on USB data lines. Typically, the capacitance should be less than 1pF. It is recommended to use an ESD protection component such as ESD9L5.0ST5G provided by On Semiconductor (www.onsemi.com).

D3 is suggested to select the diode with anti-ESD and voltage surge function, or user could add a TVS for surge clamping. The recommend TVS please refer to table 7.

NOTE

The USB_DN and USB_DP nets must be traced by 90Ohm+/-10% differential impedance.

3.4.2. USB_BOOT

Module can enter in force download mode by USB_BOOT.

Table 11: USB_BOOT description

PIN No	PIN Name	I/O	description	Power domain	Default status	Index
85	USB_BOOT	DI	USB boot	1.8V	B-PD	

If the module download failed, then customer can make module enter download mode via this Pin. Before the module power on, pull up the USB_BOOT to VDD_1V8，then push the PWRKEY to power on module, when the module enter download mode, the pull up should be removed.
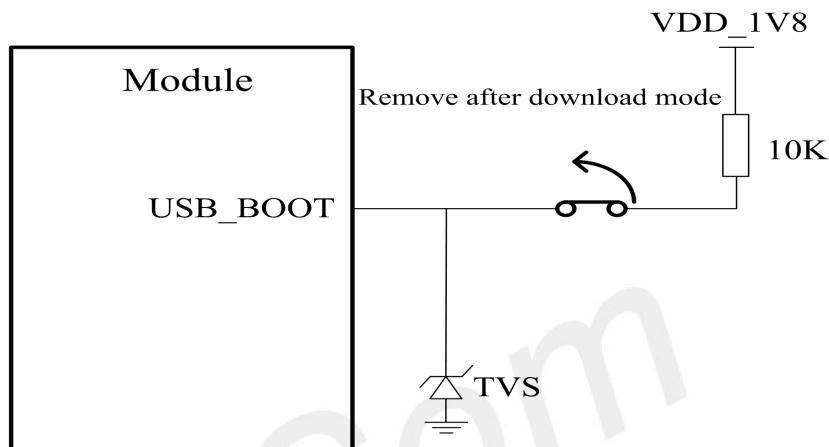
Figure 20: USB_BOOT circuit

Customer can check the download port in the device management.

Figure 21: Force download port

3.4.3.   USB_ID

Module support OTG function，but the USB_VBUS(PIN 11) can not supply device with 5V, so customer should design the circuit to power the USB device.For the detail circuit, customer could refer to *SIM7600 Series EMMC-Reference Design*.

Table 12: USB_ID description

PIN No	PIN Name	I/O	Function description	Domain	Default Status	index
16	USB_ID	DI	High level: module in USB device mode. Low level: module in USB host mode.	1.8V	DI-PH	
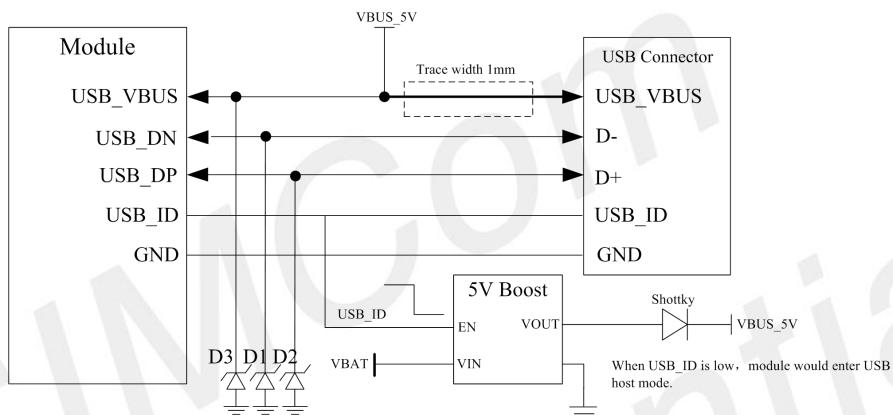
Figure 22: USB_OTG diagram

3.5 HSIC interface

HSIC is a 2-signal source synchronous serial interface which uses 240MHz DDR signaling to provide High-Speed 480Mbps USB transfers which are 100% host driver compatible with traditional USB cable-connected topologies. Full-Speed (FS) and Low-Speed (LS) USB transfers are not directly supported by the HSIC interface (a HSIC enabled hub can provide FS and LS support, as well as IC_USB support) The differences between HSIC and USB2.0 are listed below:

Table 13: Key differences between HSIC and HS-USB

HSIC	USB2.0
Signal-ended signaling at 1.2 V	Differential signaling
Two signals – STROBE, DATA	Four wires – Ground, D+, D-, VBUS
Double data rate signaling	Data inferred from differential signaling
HS-USB 480 Mbps only	HS/FS/LS support
Maximum trace length of 10 cm	Maximum cable length of 5 m
No HS chirp protocol	HS chirp protocol

Lower power consumption (digital)	Higher power consumption (analog)
No concept of disconnect	Hot plug/play support

Module implements a HSIC interface compliant with the HSIC1.0 specification which can be used to connect to the external IC.

> **NOTE**
>
> The module HSIC default work as HSIC to LAN function, if user have any other question, please contact SIMCom for more details.

3.6 SGMII Interface

Module provides a SGMII interface with an Ethernet MAC embedded, users could add a PHY to connect to the Ethernet, and the PHY device could be controlled by the MDIO interface and other dedicated signals. Two Ethernet PHY are supported: AR8031/AR8033 (Qualcomm) and BCM89820 (Broadcom). The AR8031/AR8033 is used for the industrial field and the BCM89820 is dedicated for the automotive field. Main features of SGMII:

- Ethernet Mac integrated in the module
- IEEE 802.3 Ethernet 10/100/1000Mbps, SGMII IF
- Supports IEEE 1588, Precision Time Protocol (PTP)
- Full duplex rated to 1 Gbps
- Half/full duplex for 10/100 Mbps
- Can be connected to external Ethernet PHY like AR8031/AR8033(industrial 10/100/1000Mbps), BCM89820(automotive 10/100Mbps)
- Uses 8B10B encoding of data with effective baud data rate of 1 Gbps, data rate is always 1.25 Gbps (or DDR clock is always at 625 MHz)

Main features of MDIO:
- Host mode only
- Dual voltage: 1.8 V or 2.85 V operation
- Default signal frequency: 6.25MHz
- MDIO_DATA is OD-gate, and requires an external 1.5 kΩ pull-up resistor to VMDIO.

For the AR8031/AR8033, User should provide 3.3V to power the external Ethernet PHY system and the current should be more than 200mA.

3.6.1 Reference schematic with AR8033
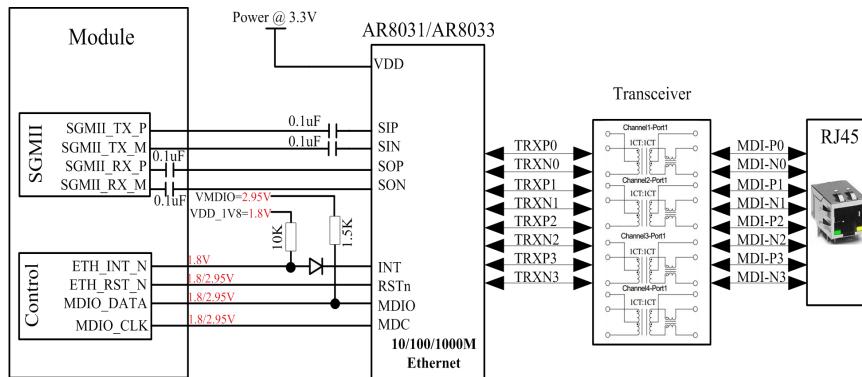
Figure 23: Reference circuit with AR8033

For the BCM89820, Users should provide 3.3V and 1.2V to power the external Ethernet PHY system and the data interface of PHY. The current of 3.3V and 1.2V should be more than 100mA and 150mA.

3.6.2   Reference schematic with BCM89820
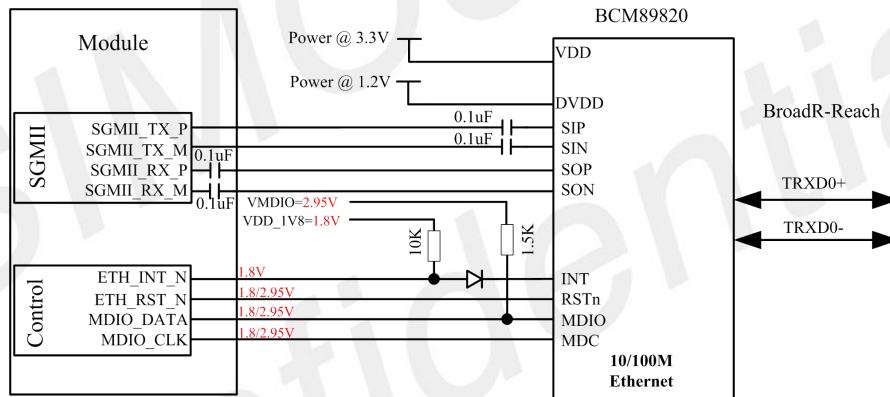
Figure 24: Reference circuit with BCM89820

NOTE

The module SGMII function default closed. If user need, please contact SIMCom for more details or refer to document [28]

3.7 USIM Interface

Module supports both 1.8V and 3.0V USIM Cards.

Table 14: USIM electronic characteristic in 1.8V mode (USIM_VDD=1.8V)

Symbol	Parameter	Min.	Typ.	Max.	Unit
USIM_VDD	LDO power output voltage	1.75	1.8	1.95	V
V_{IH}	High-level input voltage	0.65*USIM_VDD	-	USIM_VDD +0.3	V
V_{IL}	Low-level input voltage	-0.3	0	0.35*USIM_VDD	V
V_{OH}	High-level output voltage	USIM_VDD -0.45	-	USIM_VDD	V
V_{OL}	Low-level output voltage	0	0	0.45	V

Table 15: USIM electronic characteristic 3.0V mode (USIM_VDD=2.95V)

Symbol	Parameter	Min.	Typ.	Max.	Unit
USIM_VDD	LDO power output voltage	2.75	2.95	3.05	V
V_{IH}	High-level input voltage	0.65*USIM_VDD	-	USIM_VDD +0.3	V
V_{IL}	Low-level input voltage	-0.3	0	0.25*USIM_VDD	V
V_{OH}	High-level output voltage	USIM_VDD -0.45	-	USIM_VDD	V
V_{OL}	Low-level output voltage	0	0	0.45	V

3.7.1   USIM Application Guide

It is recommended to use an ESD protection component such as ESDA6V1W5 produced by ST (www.st.com) or SMF15C produced by ON SEMI (www.onsemi.com). Note that the USIM peripheral circuit should be close to the USIM card socket. The following figure shows the 6-pin SIM card holder reference circuit.
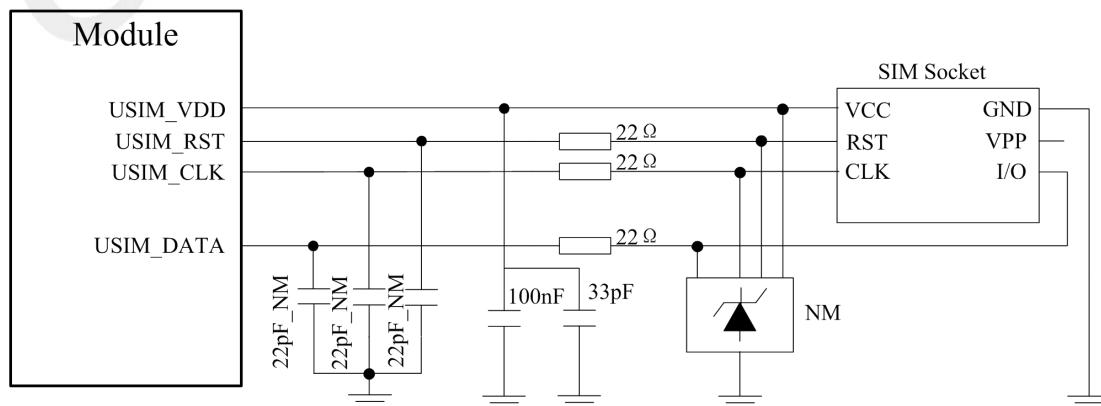
Figure 25: USIM interface reference circuit

USIM_DATA has been pulled up with a 10KΩ resistor to USIM_VDD in module. A 100nF capacitor on USIM_VDD is used to reduce interference. For more details of AT commands about USIM, please refer to document [1].USIM_CLK is very important signal, the rise time and fall time of USIM_CLK should be less than 40ns, otherwise the USIM card might not be initialized correctly.

The USIM_DET pin is used for detection of the USIM card hot plug in. User can select the 8-pin USIM card holder to implement USIM card detection function.

The following figure shows the 8-pin SIM card holder reference circuit.
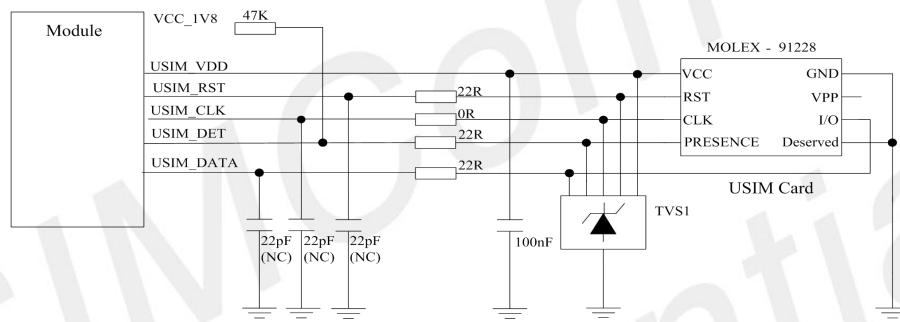
Figure 26: USIM interface reference circuit with USIM_DET

If the USIM card detection function is not used, user can keep the USIM_DET pin open.

3.7.2 USIM Design Notice

SIM card circuit is susceptible; the interference may cause the SIM card failures or some other situations, so it is strongly recommended to follow these guidelines while designing:

- Make sure that the SIM card holder should be far away from the antenna while in PCB layout.
- SIM traces should keep away from RF lines, VBAT and high-speed signal lines.
- The traces should be as short as possible.
- Keep SIM holder's GND connect to main ground directly.
- Shielding the SIM card signal by ground.
- Recommended to place a 0.1～1uF capacitor on USIM_VDD line and keep close to the holder.
- The rise/fall time of USIM_CLK should not be more than 40ns.
- Add some TVS and the parasitic capacitance should not exceed 60pF.

3.7.3 Recommended USIM Card Holder

It is recommended to use the 6-pin USIM socket such as C707 10M006 512 produced by Amphenol. User can visit http://www.amphenol.com for more information about the holder.
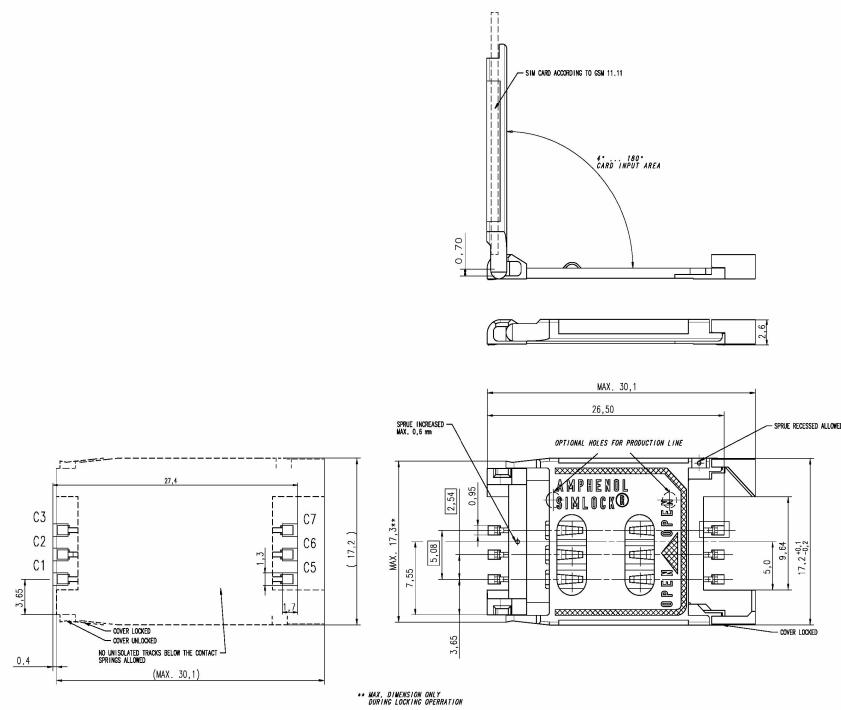
Figure 27: Amphenol SIM card socket

Table 16: Amphenol USIM socket pin description

Pin	Signal	Description
C1	USIM_VDD	USIM Card Power supply.
C2	USIM_RST	USIM Card Reset.
C3	USIM_CLK	USIM Card Clock.
C5	GND	Connect to GND.
C6	VPP	NC
C7	USIM_DATA	USIM Card data I/O.

3.8 PCM Interface

Module provides a PCM interface for external codec, which can be used in master mode with short sync and 16 bits linear format.

Table 17: PCM format

Characteristics	Specification
Line Interface Format	Linear(Fixed)
Data length	16bits(Fixed)
PCM Clock/Sync Source	Master Mode(Fixed)

PCM Clock Rate	2048 KHz (Fixed)
PCM Sync Format	Short sync(Fixed)
Data Ordering	MSB

NOTE

For more details about PCM AT commands, please refer to document [1].

3.8.1 PCM timing

Module supports 2.048 MHz PCM data and sync timing for 16 bits linear format codec.
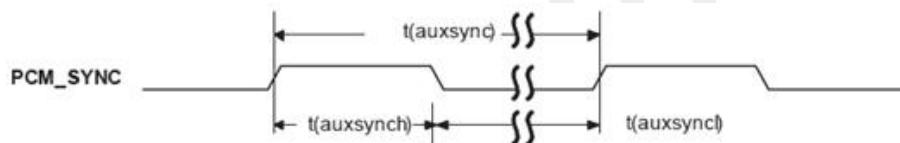
Figure 28: PCM_SYNC timing
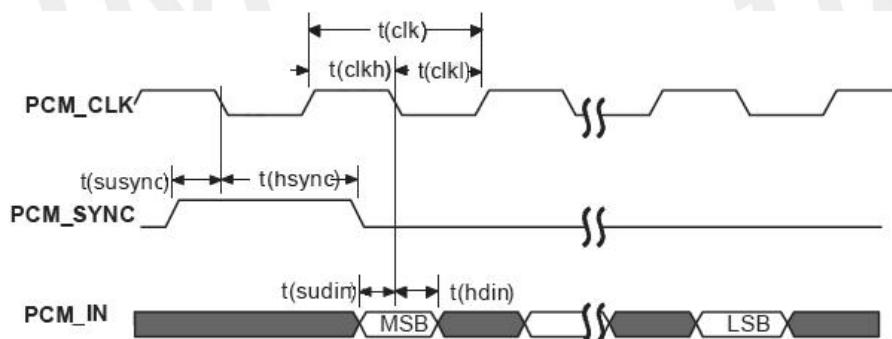
Figure 29: EXT codec to module timing
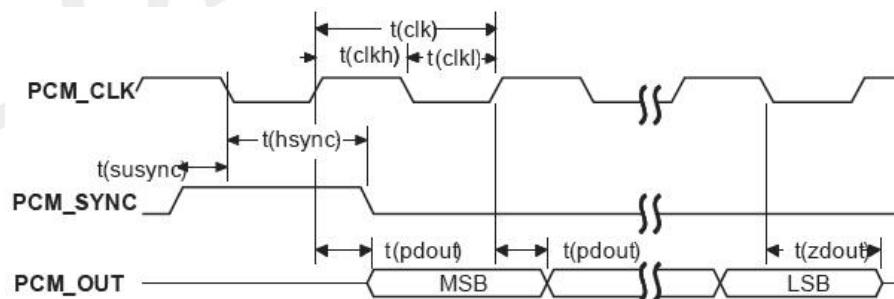
Figure 30: Module to EXT codec timing

Table 18: PCM timing parameters

Parameter	Description	Min.	Typ.	Max.	Unit
T(sync)	PCM_SYNC cycle time	–	125	–	µs
T(synch)	PCM_SYNC high level time	–	488	–	ns
T(syncl)	PCM_SYNC low level time	–	124.5	–	µs
T(clk)	PCM_CLK cycle time	–	488	–	ns
T(clkh)	PCM_CLK high level time	–	244	–	ns
T(clkl)	PCM_CLK low level time	–	244	–	ns
T(susync)	PCM_SYNC setup time high before falling edge of PCM_CLK	–	244	–	ns
T(hsync)	PCM_SYNC hold time after falling edge of PCM_CLK	–	244	–	ns
T(sudin)	PCM_IN setup time before falling edge of PCM_CLK	60	–	–	ns
T(hdin)	PCM_IN hold time after falling edge of PCM_CLK	10	–	–	ns
T(pdout)	Delay from PCM_CLK rising to PCM_OUT valid	–	–	60	ns
T(zdout)	Delay from PCM_CLK falling to PCM_OUT HIGH-Z	–	160	-	ns

3.8.2   PCM Application Guide

The following figure shows the external codec reference design.
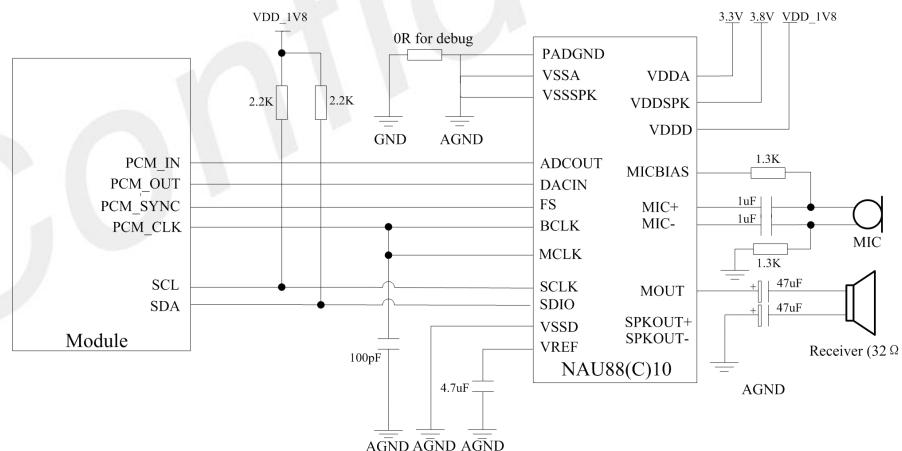
Figure 31: Audio codec reference circuit

3.9 SD Interface

Module provides a 4-bit SD/MMC/eMMC interface with clock rate up to 200 MHz.

When connected to a SD or MMC card, the voltage of SD interface is 1.8/2.85V, which is compatible with

Secure Digital Physical Layer Specification version 3.0 and SDIO Card Specification version 3.0.It supports up to 128GB SD cards.When connected to a eMMC card, the interface voltage will be a single 1.8V, which is compatible with eMMC Specification, version 4.5. It supports up to 128GB eMMC cards.

Table 19: SD/MMC electronic characteristic as 2.85V

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{IH}	High-level input voltage	0.65*2.85	-	2.85+0.3	V
V_{IL}	Low-level input voltage	-0.3	0	0.25*2.85	V
V_{OH}	High-level output voltage	0.75*2.85	2.85	2.85	V
V_{OL}	Low-level output voltage	0	0	0.15*2.85	V

Table 20: SD/MMC/eMMC electronic characteristic as 1.8V

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{IH}	High-level input voltage	0.7*1.8	-	1.8+0.2	V
V_{IL}	Low-level input voltage	-0.3	0	0.3*1.8	V
V_{OH}	High-level output voltage	1.8-0.4	1.8	1.8	V
V_{OL}	Low-level output voltage	0	0	0.45	V

Users should provide 2.85V to power SD card system and the current should more than 350mA, which is showed below as VCC_SD. ESD/EMI components should be arranged beside SD card socket. Refer to the following application circuit.
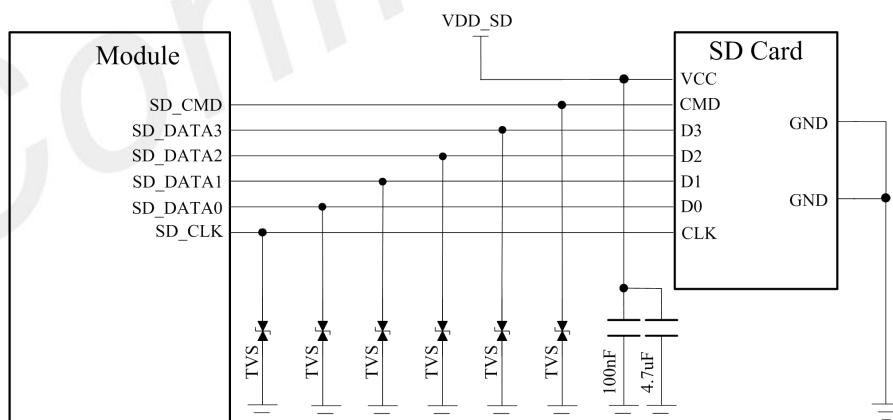
Figure 32: SD reference circuit

Users should provide 2.85V to power eMMC card system and 1.8V to power the SDIO_DATA/CMD/CLK signals. The source of 2.85V should be able to provide more than 500mA* which showed below as VCC_eMMC, as the source of 1.8V should be able to provide more than 300mA* which showed below as VCCQ_1V8. ESD/EMI components should be arranged close to the eMMC card. Refer to the following application circuit.
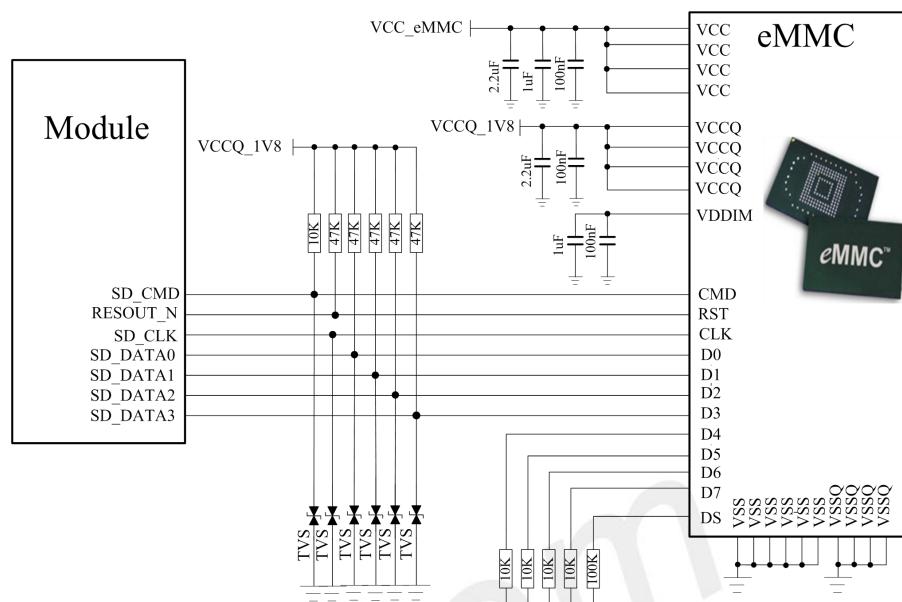
Figure 33: eMMC reference circuit

> **NOTE**
>
> For the current of VCC_eMMC and VCCQ_1V8, users should better refer to the related datasheet of eMMC which is used. The listed current of 500mA and 300mA are just for your reference.

SD/MMC/eMMC card layout guide lines:

- Protect SD card signals from noisy signals (clocks, SMPS, etc.).
- Up to 200 MHz clock rate, 50 Ω nominal, ±10% trace impedance
- CLK to DATA/CMD length matching < 1 mm
- Total routing length < 50 mm
- Spacing to all other signals = 2x line width
- Bus capacitance < 10 pF

3.10 I2C Interface

Module provides a I2C interface compatible with I2C specification, version 5.0, with clock rate up to 400 kbps. Its operation voltage is 1.8V.

The following figure shows the I2C bus reference design.
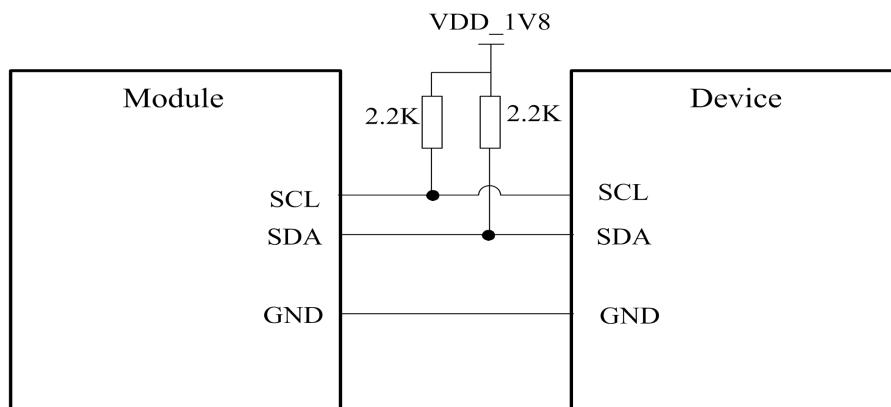
Figure 34: I2C reference circuit

NOTE

1. SDA and SCL do not have pull-up resistors in module. So, 2 external pull up resistors are needed in application circuit.

2. "AT+CRIIC and AT+CWIIC" AT commands could be used to read/write register values of the I2C peripheral devices. For more details about AT commands please refer to document [1].

3.11 SDIO Interface

Module provides a 4 bit 1.8V SDIO interface for WLAN solution with W58 module.

NOTE

Please refer to document "SIM7600+W58 Reference Design".

3.12 SPI Interface

Module provides SPI interface and the clock rate is 50MHZ, it an only be used as master mode, and the IO is 1.8V.

NOTE

This function is reserved. For detail information please contact with FAE.

3.13 Network status

The NETLIGHT pin is used to control Network Status LED, its reference circuit is shown in the following figure.
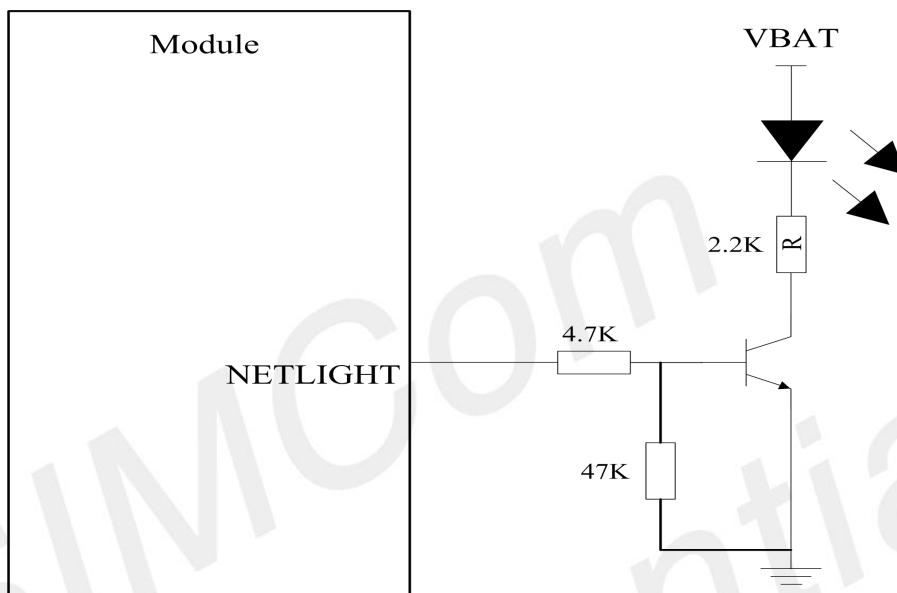
Figure 35: NETLIGHT reference circuit

> **NOTE**
>
> The value of the resistor named "R" depends on the LED characteristic.

Table 21: NETLIGHT pin status

NETLIGHT pin status	Module status
Always On	Searching Network; Call Connect(include VOLTE,SRLTE)
200ms ON, 200ms OFF	Data Transmit; 4G registered;
800ms ON, 800ms OFF	2G/3G registered network
OFF	Power off ;Sleep

> **NOTE**
>
> NETLIGHT output low level as "OFF", and high level as "ON".

3.14 Flight Mode Control

The FLIGHTMODE pin can be used to control module to enter or exit the Flight mode. In Flight mode, the RF circuit is closed to prevent interference with other equipments and minimize current consumption. Bidirectional ESD protection component is suggested to add on FLIGHTMODE pin, its reference circuit is shown in the following figure.
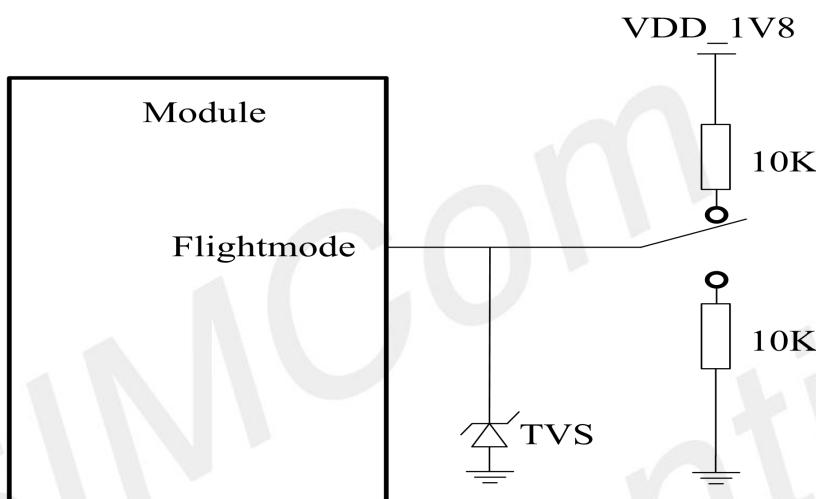
Figure 36: Flight mode switch reference circuit

Table 22: FLIGHTMODE pin status

FLIGHTMODE pin status	Module operation
Input Low Level	Flight Mode: RF is closed
Input High Level	AT+CFUN=0: RF is closed AT+CFUN=1:RF is working

3.15 LCD controller

LCD controller features include:

● 9Data interface width: 8 bit and 9 bits
● Resolution: HVGA, 320 (V) × 480 (H) pixels at up to 30 fps
Resolution is scalable; for example, HVGA 480x320 is usable at 30 fps
Support for smart panel LCD devices
● Color depth: up to 18 bits/pixel
● LCD interfaces:
MIPI DBI version 2.0, type B

8-bit and 9-bit parallel data interface – 8-bit interface uses the lower 8 bits of the LCD bus (D0 to D7)
● Autonomous data movement capabilities (via BAM)
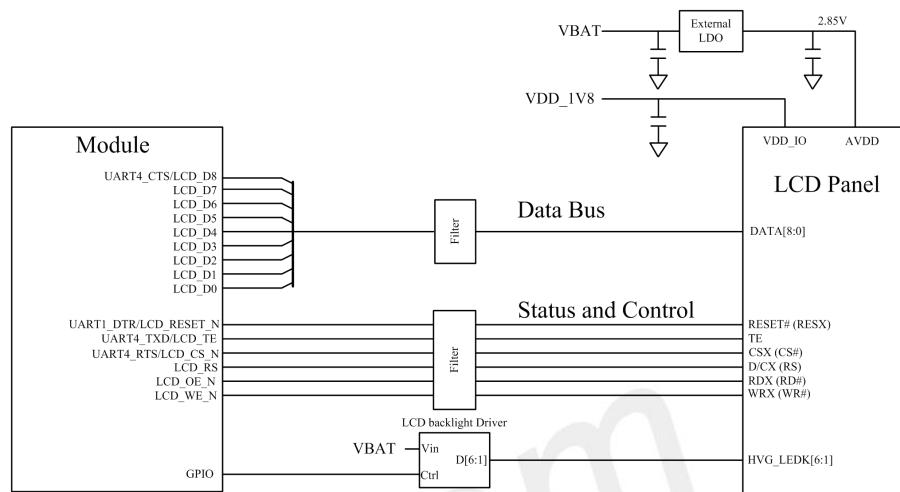
Figure 37: LCD diagram

3.16 Other interface

3.16.1 Sink Current Source

The ISINK pin is VBAT tolerant and intended to drive some passive devices, such as LCD backlight and white LED, etc. Its output current can be up to 40mA and be set by the AT command "AT+ CLEDITST".

Table 23: Sink current electronic characteristic

Symbol	Description	Min.	Typ.	Max.	Unit
V_{ISINK}	Voltage tolerant	0.5	-	VBAT	V
I_{ISINK}	Current tolerant	0	-	40	mA

ISINK is a ground-referenced current sink. The following figure shows its reference circuit.
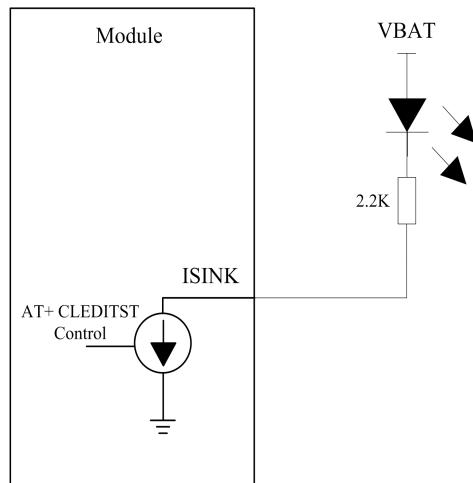
Figure 38: ISINK reference circuit

> **NOTE**
>
> The sinking current can be adjusted to meet the design requirement through the AT command "AT+ CLEDITST =<0>, <value>".The "value" ranges from 0 to 8, on behalf of the current from 0mA to 40mA by 5mA step.

3.16.2 ADC

Module has 3 dedicated ADC pins named ADC0, ADC1 and ADC2.They are available for digitizing analog signals such as battery voltage and so on. These electronic specifications are shown in the following table.

Table 24: Electronic characteristics

Characteristics	Min.	Typ.	Max.	Unit
Resolution	–	15	–	Bits
Conversion time	–	442	–	us
Input Range	0.1		1.7	V
Input serial resistance	1	–	–	MΩ

> **NOTE**
>
> "AT+CADC0", "AT+CADC" and "AT+CADC2" can be used to read the voltage of the ADC0, ADC1 and ADC2 pins, for more details, please refer to document [1].

3.16.3 LDO

Module has a LDO power output, named VDD_AUX. its output voltage is 2.85V by default, Users can switch the LDO on or off by the AT command "AT+CVAUXS" and configure its output voltage by the AT command "AT+CVAUXV".

Table 25: Electronic characteristic

Symbol	Description	Min.	Typ.	Max.	Unit
V_{VDD_AUX}	Output voltage	1.7	2.85	3.05	V
I_O	Output current	-	-	150	mA

NOTE

For more details of AT commands about VDD_AUX, please refer to document [1].

4. RF Specifications

4.1 GSM/UMTS/LTE RF Specifications

Table 26: Conducted transmission power

Frequency	Power	Min.
GSM850	33dBm ±2dB	5dBm ± 5dB
EGSM900	33dBm ±2dB	5dBm ± 5dB
DCS1800	30dBm ±2dB	0dBm ± 5dB
PCS1900	30dBm ±2dB	0dBm ± 5dB
GSM850 (8-PSK)	27dBm ±3dB	5dBm ± 5dB
EGSM900 (8-PSK)	27dBm ±3dB	5dBm ± 5dB
DCS1800 (8-PSK)	26dBm +3/-4dB	0dBm ±5dB
PCS1900 (8-PSK)	26dBm +3/-4dB	0dBm ±5dB
WCDMA B1	24dBm +1/-3dB	<-50dBm
WCDMA B2	24dBm +1/-3dB	<-50dBm
WCDMA B4	24dBm +1/-3dB	<-50dBm
WCDMA B5	24dBm +1/-3dB	<-50dBm
WCDMA B6	24dBm +1/-3dB	<-50dBm
WCDMA B8	24dBm + 1/-3dB	<-50dBm
WCDMA B19	24dBm +1/-3dB	<-50dBm
LTE-FDD B1	23dBm +/-2.7dB	<-40dBm
LTE-FDD B2	23dBm +/-2.7dB	<-40dBm
LTE-FDD B3	23dBm +/-2.7dB	<-40dBm
LTE-FDD B4	23dBm +/-2.7dB	<-40dBm
LTE-FDD B5	23dBm +/-2.7dB	<-40dBm
LTE-FDD B7	23dBm +/-2.7dB	<-40dBm
LTE-FDD B8	23dBm +/-2.7dB	<-40dBm
LTE-FDD B12	23dBm +/-2.7dB	<-40dBm
LTE-FDD B13	23dBm +/-2.7dB	<-40dBm
LTE-FDD B18	23dBm +/-2.7dB	<-40dBm
LTE-FDD B19	23dBm +/-2.7dB	<-40dBm
LTE-FDD B20	23dBm +/-2.7dB	<-40dBm
LTE-FDD B25	23dBm +/-2.7dB	<-40dBm

LTE-FDD B26	23dBm +/-2.7dB	<-40dBm
LTE-FDD B28	23dBm +/-2.7dB	<-40dBm
LTE-FDD B66	23dBm +/-2.7dB	<-40dBm
LTE-TDD B34	23dBm +/-2.7dB	<-40dBm
LTE-TDD B38	23dBm +/-2.7dB	<-40dBm
LTE-TDD B39	23dBm +/-2.7dB	<-40dBm
LTE-TDD B40	23dBm +/-2.7dB	<-40dBm
LTE-TDD B41	23dBm +/-2.7dB	<-40dBm

Table 27: Operating frequencies

Frequency	Receiving	Transmission
GSM850	869～894MHz	824～849 MHz
EGSM900	925～960MHz	880～915 MHz
DCS1800	1805～1880 MHz	1710～1785 MHz
PCS1900	1930~1990 MHz	1850~1910 MHz
WCDMA B1	2110～2170 MHz	1920～1980 MHz
WCDMA B2	1930~1990 MHz	1850~1910 MHz
WCDMA B4	2110~2155MHz	1710~1755MHz
WCDMA B5	869～894 MHz	824～849 MHz
WCDMA B6	877~882MHz	832~837MHz
WCDMA B8	925～960 MHz	880～915 MHz
WCDMA B19	875~890MHz	835~845MHz
The LTE Operating frequencies are shown in the following table 24. Note: Operating frequencies of LTE TDD B41 for the module is 100MHz BW, 2555～2655 MHz		
GPS	1574.4 ～1576.44 MHz	-
GLONASS	1598 ～1606 MHz	-
BD	1559 ～1563 MHz	

Table 28: E-UTRA operating bands

E-UTRA Operating Band	Uplink (UL) operating band	Downlink (DL) operating band	Duplex Mode
1	1920 ~1980 MHz	2110 ~2170 MHz	FDD
2	1850~1910 MHz	1930~1990 MHz	FDD
3	1710 ~1785 MHz	1805 ~1880 MHz	FDD
4	1710~1755MHz	2110~2155MHz	FDD
5	824～849 MHz	869～894MHz	FDD
7	2500~2570MHz	2620~2690MHz	FDD
8	880 ~915 MHz	925 ~960 MHz	FDD

12	699~716MHz	728~746MHz	FDD
13	777~787MHz	746~757MHz	FDD
18	815~830MHz	860~875MHz	FDD
19	830~845MHz	875~890MHz	FDD
20	832~862MHz	791~ 821MHz	FDD
25	1850~1915MHz	1930~1995MHz	FDD
26	814~849MHz	859~894MHz	FDD
28	703~748MHz	758~803MHz	FDD
66	1710~1780MHz	2110~2200MHz	FDD
34	2010~2025MHz	2010~2025MHz	TDD
38	2570 ~2620 MHz	2570 ~2620 MHz	TDD
39	1880~1920MHz	1880~1920MHz	TDD
40	2300 ~2400 MHz	2300 ~2400 MHz	TDD
41	2496~2696 MHz	2496~2696 MHz	TDD

Table 29: Conducted receive sensitivity

Frequency	Receive sensitivity(Typical)	Receive sensitivity(MAX)
GSM850	< -109dBm	3GPP
EGSM900	< -109dBm	3GPP
DCS1800	< -109dBm	3GPP
PCS1900	< -109dBm	3GPP
WCDMA B1	< -110dBm	3GPP
WCDMA B2	< -110dBm	3GPP
WCDMA B4	< -110dBm	3GPP
WCDMA B5	< -110dBm	3GPP
WCDMA B6	< -110dBm	3GPP
WCDMA B8	< -110dBm	3GPP
WCDMA B19	< -110dBm	3GPP
LTE FDD/TDD	See table 26.	3GPP

Table 30: Reference sensitivity (QPSK)

E-UTRA band	3GPP standard						Test Value
	1.4 MHz	3 MHz	5 MHz	10 MHz	15 MHz	20 MHz	
FDD B1	-	-	-100	-97	-95.2	-94	-985
FDD B2	-102.7	-99.7	-98	-95	-93.2	-92	-98.5
FDD B3	-101.7	-98.7	-97	-94	-92.2	-91	-99
FDD B4	-104.7	-101.7	-100	-97	-95.2	-94	-98

FDD B5	-103.2	-100.2	-98	-95			-99.5
FDD B7			-98	-95	-93.2	-92	-96.5
FDD B8	-102.2	-99.2	-97	-94			-98.5
FDD B12	-101.7	-98.7	-97	-94			-98.5
FDD B13			-97	-94			-97.5
FDD B18			-100	-97	-95.2		-99.5
FDD B19			-100	-97	-95.2		-99.5
FDD B20			-97	-94	-91.2	-90	-96.5
FDD B25	-101.2	-98.2	-96.5	-93.5	-91.7	-90.5	-98.5
FDD B26	-102.7	-99.7	-97.5	-94.5	-92.7		-99.5
FDD B28		-100.2	-98.5	-95.5	-93.7	-91	99.5
FDD B66	-104.7	-101.7	-100	-97	-95.2	-94	-98.5
FDD B34			-100	-97	-95.2		-99
FDD B38	-	-	-100	-97	-95.2	-94	-97.5
FDD B39			-100	-97	-95.2		-99.5
FDD B40	-	-	-100	-97	-95.2	-94	-98
FDD B41	-	-	-99	-96	-94.2	-93	-99

NOTE

Test value @ 10MHz

4.2 GSM /UMTS/LTE Antenna Design Guide

Users should connect antennas to module's antenna pads through micro-strip line or other types of RF trace and the trace impedance must be controlled in 50Ω. SIMCom recommends that the total insertion loss between the antenna pads and antennas should meet the following requirements:

Table 31: Trace loss

Frequency	Loss
700MHz-960MHz	<0.5dB
1710MHz-2170MHz	<0.9dB
2300MHz-2650MHz	<1.2dB

To facilitate the antenna tuning and certification test, a RF connector and an antenna matching circuit should be added. The following figure is the recommended circuit.
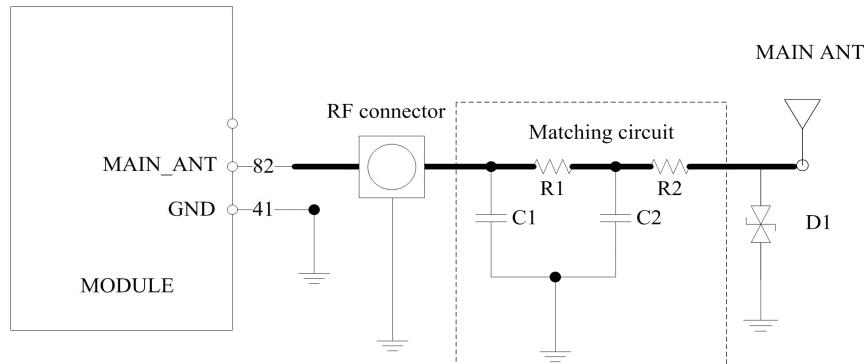
Figure 39: Antenna matching circuit (MAIN_ANT)

In above figure, the components R1, C1, C2 and R2 are used for antenna matching, the values of components can only be achieved after the antenna tuning and usually provided by antenna vendor. By default, the R1, R2 are 0Ω resistors, and the C1, C2 are reserved for tuning. The component D1 is a TVS for ESD protection, and it is optional for users according to application environment.

The RF test connector is used for the conducted RF performance test, and should be placed as close as to the module's MAIN_ANT pin. The traces impedance between module and antenna must be controlled in 50Ω.
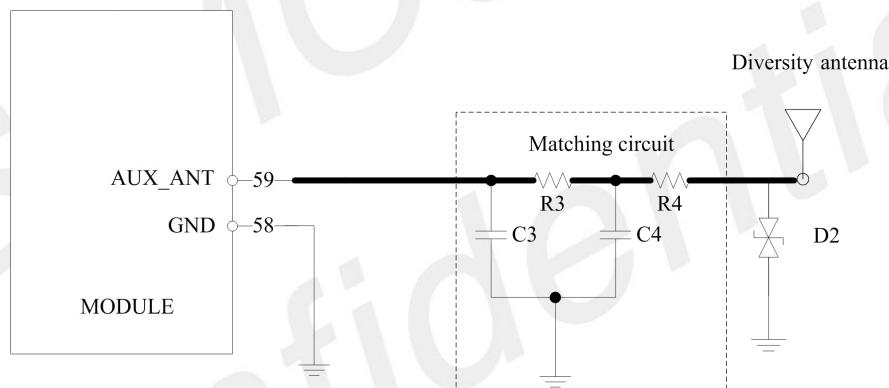
Figure 40: Antenna matching circuit (AUX_ANT)

In above figure, R3, C3, C4 and R4 are used for auxiliary antenna matching. By default, the R3, R4 are 0Ωresistors, and the C3, C4 are reserved for tuning. D2 is a TVS for ESD protection, and it is optional for users according to application environment. Two TVS are recommended in the table below.

Table 32: Recommended TVS

Package	Part Number	Vender
0201	LXES03AAA1-154	Murata
0402	LXES15AAA1-153	Murata

NOTE

SIMCom suggests the LTE auxiliary antenna to be kept on, since there are many high bands in the designing of LTE-TDD, such as band38, band40 and band41. Because of the high insert loss of the RF

cable and layout lines, the receiver sensitivity of these bands above will have risk to meet the authentication without the diversity antenna. For more details about auxiliary antenna design notice, please refer to document [25].

4.3 GNSS

Module merges GNSS (GPS/GLONASS/BD) satellite and network information to provide a high-availability solution that offers industry-leading accuracy and performance. This solution performs well, even in very challenging environmental conditions where conventional GNSS receivers fail, and provides a platform to enable wireless operators to address both location-based services and emergency mandates.

4.3.1 GNSS Technical specification

- Tracking sensitivity: -159 dBm（GPS）/-158 dBm（GLONASS）/-159 dBm（BD）
- Cold-start sensitivity: -148 dBm
- Accuracy (Open Sky): 2.5m (CEP50)
- TTFF (Open Sky) : Hot start <1s, Cold start<35s
- Receiver Type: 16-channel, C/A Code
- GPS L1 Frequency: 1575.42±1.023MHz
- GLONASS: 1597.5~1605.8 MHz
- BD: 1559.05~1563.14 MHz
- Update rate: Default 1 Hz
- GNSS data format: NMEA-0183
- GNSS Current consumption : 100mA (GSM/UMTS/LTE Sleep ,in total on VBAT pins)
- GNSS antenna: Passive/Active antenna

NOTE

If the antenna is active type, the power should be given by main board because there is no power supply on the GPS antenna pad. If the antenna is passive, we suggest add external LNA .

4.3.2 GNSS Application Guide

Users can adopt an active antenna or a passive antenna to module. If using a passive antenna, an external LNA is a must to get better performance. The following figures are the reference circuits.
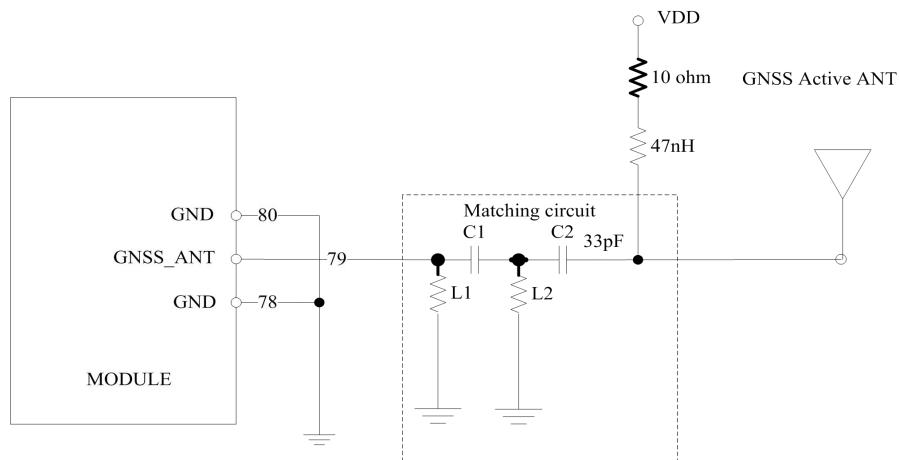
Figure 41: Active antenna circuit
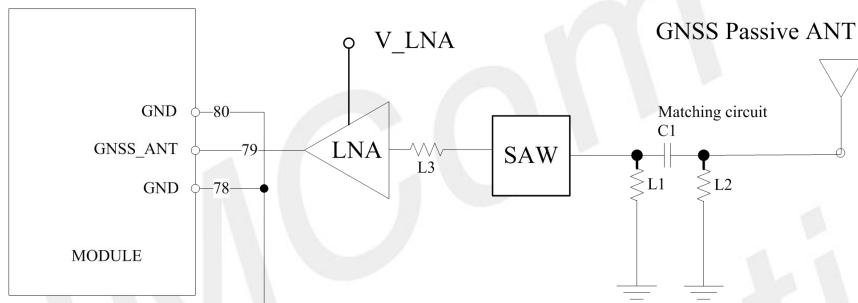
Figure 42: Passive antenna circuit (Default)

In above figures, the components C1, L1 and L2 are used for antenna matching. Usually, the values of the components can only be achieved after antenna tuning and usually provided by antenna vendor. C2 is used for DC blocking. L3 is the matching component of the external LNA, and the value of L3 is determined by the LNA characteristic and PCB layout. Both VDD of active antenna and V_LNA need external power supplies which should be considered according to active antenna and LNA characteristic. LDO/DCDC is recommended to get lower current consuming by shutting down active antennas and LNA when GNSS is not working.

GNSS can be tested by NMEA port. NMEA sentences can be obtained through UART or USB automatically. NMEA sentences include GSV, GGA, RMC, GSA, and VTG. Before using GNSS, user should configure module in proper operating mode by AT command. Please refer to related documents for details. module can also get position location information through AT directly.

<div style="border:1px solid red;">NOTE</div>

GNSS is closed by default and can be started by AT+CGPS. The AT command has two parameters, the first is on/off, and the second is GNSS mode. Default mode is standalone mode.
AGPS mode needs more support from the mobile telecommunication network. Please refer to document [24] for more details.

5. Electrical Specifications

5.1 Absolute maximum ratings

Absolute maximum rating for digital and analog pins of module are listed in the following table:

Table 33: Absolute maximum ratings

Parameter	Min.	Typ.	Max.	Unit
Voltage at VBAT	-0.5	-	4.7	V
Voltage at USB_VBUS	-0.5	-	5.5	V
Voltage at digital pins (RESET,SPI,Keypad,GPIO,I2C,UART,PCM)	-0.3	-	2.1	V
Voltage at digital pins (SD,USIM)	-0.3	-	3.05	V
Voltage at PWRKEY	-0.3	-	1.8	V

5.2 Operating conditions

Table 34: Recommended operating ratings

Parameter	Min.	Typ.	Max.	Unit
Voltage at VBAT	3.4	3.8	4.2	V
Voltage at USB_VBUS	3.0	5.0	5.25	V

Table 35: 1.8V Digital I/O characteristics*

Parameter	Description	Min.	Typ.	Max.	Unit
V_{IH}	High-level input voltage	1.17	1.8	2.1	V
V_{IL}	Low-level input voltage	-0.3	0	0.63	V
V_{OH}	High-level output voltage	1.35	-	1.8	V
V_{OL}	Low-level output voltage	0	-	0.45	V
I_{OH}	High-level output current(no pull	-	2	-	mA

	down resistor)				
I$_{OL}$	Low-level output current(no pull up resistor)	-	-2	-	mA
I$_{IH}$	Input high leakage current (no pull down resistor)	-	-	1	uA
I$_{IL}$	Input low leakage current(no pull up resistor)	-1	-	-	uA

NOTE

These parameters are for digital interface pins, such as SPI, GPIOs (STATUS, USIM_DET), SDIO, I2C, UART, PCM, COEXn, and USB_BOOT.

The operating temperature of module is listed in the following table.

Table 36: Operating temperature

Parameter	Min.	Typ.	Max.	Unit
Normal operation temperature	-30	25	80	℃
Extended operation temperature*	-40	25	85	℃
Storage temperature	-45	25	+90	℃

NOTE

Note: Module is able to make and receive voice calls, data calls, SMS and make GSM/ UMTX/LTE traffic in -40℃ ~ +85℃. The performance will be reduced slightly from the 3GPP specifications if the temperature is outside the normal operating temperature range and still within the extreme operating temperature range.

5.3 Operating Mode

5.3.1 Operating Mode Definition

The table below summarizes the various operating modes of module product.

Table 37: Operating mode Definition

Mode		Function
Normal operation	GSM /UMTS/LTE Sleep	In this case, the current consumption of module will be reduced to the minimal level and the module can still receive paging message and SMS.
	GSM/UMTS/LTE Idle	Software is active. Module is registered to the network, and the module is ready to communicate.
	GSM/UMTS/LTE Talk	Connection between two subscribers is in progress. In this case, the power consumption depends on network settings such as DTX off/on, FR/EFR/HR, hopping sequences, and antenna.
	GPRS/EDGE/ UMTS/LTE Standby	Module is ready for data transmission, but no data is currently sent or received. In this case, power consumption depends on network settings.
	GPRS/EDGE/ UMTS/LTE Data transmission	There is data transmission in progress. In this case, power consumption is related to network settings (e.g. power control level); uplink/downlink data rates, etc.
Minimum functionality mode		AT command "AT+CFUN=0" AT+CSCLK=1 can be used to set the module to a minimum functionality mode without removing the power supply. In this mode, the RF part of the module will not work and the USIM card will not be accessible, but the serial port and USB port are still accessible. The power consumption in this mode is lower than normal mode.
Flight mode		AT command "AT+CFUN=4" or pulling down the FLIGHTMODE pin can be used to set the module to flight mode without removing the power supply. In this mode, the RF part of the module will not work, but the serial port and USB port are still accessible. The power consumption in this mode is lower than normal mode.
Power off		Module will go into power off mode by sending the AT command "AT+CPOF" or pull down the PWRKEY pin, normally. In this mode the power management unit shuts down the power supply, and software is not active. The serial port and USB are is not accessible.

5.3.2 Sleep mode

In sleep mode, the current consumption of module will be reduced to the minimal level, and module can still receive paging message and SMS.Several hardware and software conditions must be satisfied together in order to let module enter into sleep mode:

1. UART condition
2. USB condition
3. Software condition

NOTE

Before designing, pay attention to how to realize sleeping/waking function and refer to Document [26] for more details.

5.3.3   Minimum functionality mode and Flight mode

Minimum functionality mode ceases a majority function of module, thus minimizing the power consumption. This mode is set by the AT command which provides a choice of the functionality levels.

● AT+CFUN=0: Minimum functionality
● AT+CFUN=1: Full functionality (Default)
● AT+CFUN=4: Flight mode

If module has been set to minimum functionality mode, the RF function and USIM card function will be closed. In this case, the serial port and USB are still accessible, but RF function and USIM card will be unavailable.

If module has been set to flight mode, the RF function will be closed. In this case, the serial port and USB are still accessible, but RF function will be unavailable.

When module is in minimum functionality or flight mode, it can return to full functionality by the AT command "AT+CFUN=1".

5.4 Current Consumption

The current consumption is listed in the table below.

Table 38: Current consumption on VBAT Pins (VBAT=3.8V)

GNSS	
GNSS supply current **(AT+CFUN=0,with USB connection)**	@ -140dBm，Tracking Typical: 35mA
GSM sleep/idle mode	
GSM/GPRS supply current **(GNSS off，without USB connection)**	Sleep mode@ BS_PA_MFRMS=2 Typical: 2.8mA Idle mode@ BS_PA_MFRMS=2 Typical: 18mA
UMTS sleep/idle mode	
WCDMA supply current **(GNSS off，without USB connection)**	Sleep mode @DRX=9 Typical: 3.3mA Idle mode @DRX=9 Typical: 17.5mA
EVDO supply current	Sleep mode Typical：2.0mA

(GNSS off，without USB connection)	Idle mode Typical：17.8mA
LTE sleep/idle mode	
LTE supply current	Sleep mode Typical: 4.6mA
(GNSS off，without USB connection)	Idle mode Typical: 17.5mA
GSM Talk	
EGSM900	@power level #5 Typical: 220mA
DCS1800	@ power level #5 Typical: 162mA
UMTS Talk	
WCDMA B1	@Power 24dBm　Typical: 540mA
WCDMA B5	@Power 24dBm　Typical: 431mA
WCDMA B8	@Power 24dBm　Typical: 385mA
GPRS	
EGSM900 (1 Rx,4 Tx)	@power level #5 Typical: 230 mA
DCS1800 (1 Rx,4 Tx)	@power level #0 Typical: 195 mA
EGSM900 (3Rx, 2 Tx)	@power level #5 Typical: 370 mA
DCS1800 (3Rx, 2 Tx)	@power level #0 Typical: 275 mA
EDGE	
EGSM900 (1 Rx,4 Tx)	@power level #8 Typical: 400 mA
DCS1800 (1 Rx,4 Tx)	@power level #2Typical: 300 mA
EGSM900 (3Rx, 2 Tx)	@power level #8 Typical: 320 mA
DCS1800 (3Rx, 2 Tx)	@power level #2 Typical: 230 mA
HSDPA data	
WCDMA B1	@Power 24dBm　　　Typical: 487mA
WCDMA B5	@Power 24dBm　　　Typical: 450mA
WCDMA B8	@Power 24dBm　　　Typical: 430 mA
LTE data	
LTE-FDD B1	@5MHz　　　Typical: 577mA @10MHz　　Typical: 617mA @20MHz　　Typical: 700mA
LTE-FDD B3	@5MHz　　　Typical: 572mA @10MHz　　Typical: 577mA @20MHz　　Typical: 622mA
LTE-FDD B5	@5MHz　　　Typical: 548mA @10MHz　　Typical: 566mA @20MHz　　Typical: 603mA
LTE-FDD B7	@5MHz　　　Typical: 711mA @10MHz　　Typical: 735mA @15MHz　　Typical: 776mA @20MHz　　Typical: 787mA
LTE-FDD B8	@5MHz　　　Typical: 550mA @10MHz　　Typical: 579mA
LTE-FDD B20	@5MHz　　　Typical: 561mA @10MHz　　Typical: 575mA @15MHz　　Typical: 600mA @20MHz　　Typical: 616mA
LTE-TDD B39	@5MHz　　　Typical: 270mA @10MHz　　Typical: 280mA @20MHz　　Typical: 305mA
LTE-TDD B41	@5MHz　　　Typical: 390mA @10MHz　　Typical: 396mA @20MHz　　Typical: 420mA

5.5 ESD Notes

Module is sensitive to ESD in the process of storage, transporting, and assembling. When module is mounted on the users' mother board, the ESD components should be placed beside the connectors which human body may touch, such as USIM card holder, audio jacks, switches, keys, etc. The following table shows the module ESD measurement performance without any external ESD component.

Table 39: The ESD performance measurement table (Temperature: 25℃, Humidity: 45%)

Part	Contact discharge	Air discharge
VBAT,GND	+/-5K	+/-10K
Antenna port	+/-5K	+/-10K
USB	+/-2K	+/-3K
UART	+/-2K	+/-3K
Other PADs	+/-1K	+/-2K

6. SMT Production Guide

6.1 Top and Bottom View of module
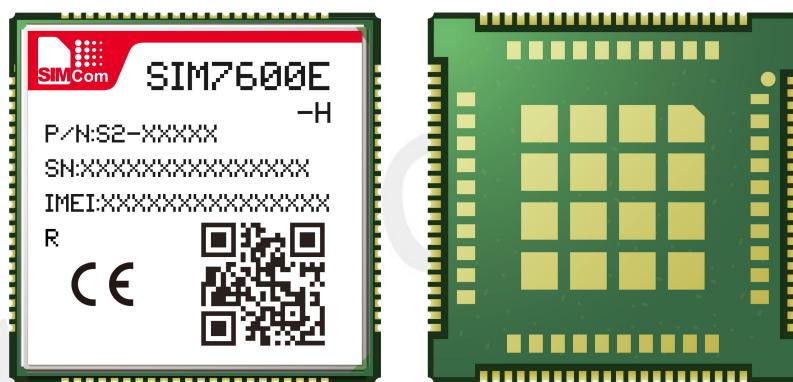
Figure 43: Top and bottom view of module

NOTE

The above is the design effect diagram of the module for reference. The actual appearance is subject to the actual product.

6.2 Label Information
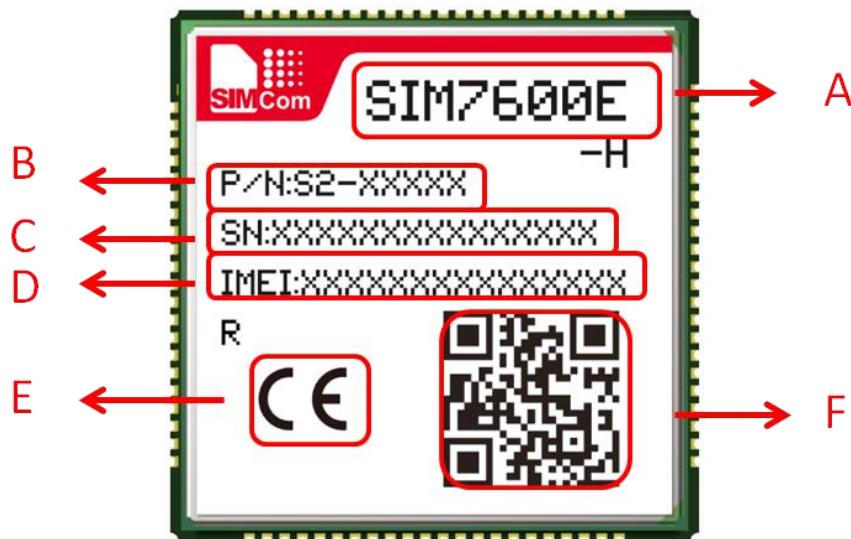
Figure 44: Label information

Table 40: The description of label information

No.	Description
A	Project name
B	Module part number
C	Serial number
D	International mobile equipment identity
E	CE certification
F	QR code

6.3 Typical SMT Reflow Profile

SIMCom provides a typical soldering profile. Therefore the soldering profile shown below is only a generic recommendation and should be adjusted to the specific application and manufacturing constraints.
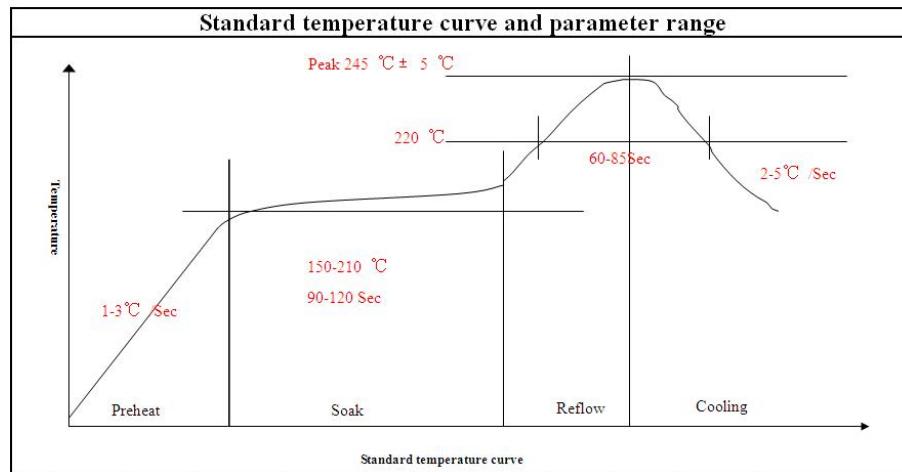
Figure 45: The ramp-soak-spike reflow profile of module

NOTE

For more details about secondary SMT, please refer to the document [21].

6.4 Moisture Sensitivity Level (MSL)

Module is qualified to Moisture Sensitivity Level (MSL) 3 in accordance with JEDEC J-STD-033. If the prescribed time limit is exceeded, users should bake module for 192 hours in drying equipment (<5% RH) at 40+5/-0°C, or 72 hours at 85+5/-5°C, or bake the module for 8 hours at 120+5/-0°C. Note that plastic tray is not heat-resistant, and only can be baked at 45° C.

Table 41: Moisture sensitivity level and floor life

Moisture Sensitivity Level (MSL)	Floor Life (out of bag) at factory ambient≤30°C/60% RH or as stated
1	Unlimited at ≦30℃/85% RH
2	1 year
2a	4 weeks
3	168 hours
4	72 hours
5	48 hours
5a	24 hours
6	Mandatory bake before use. After bake, it must be reflowed within the time limit specified on the label.

NOTE

NOTE: IPC / JEDEC J-STD-033 standard must be followed for production and storage.

6.5 Stencil Foil Design Recommendation

The recommended thickness of stencil foil is more than 0.15mm.
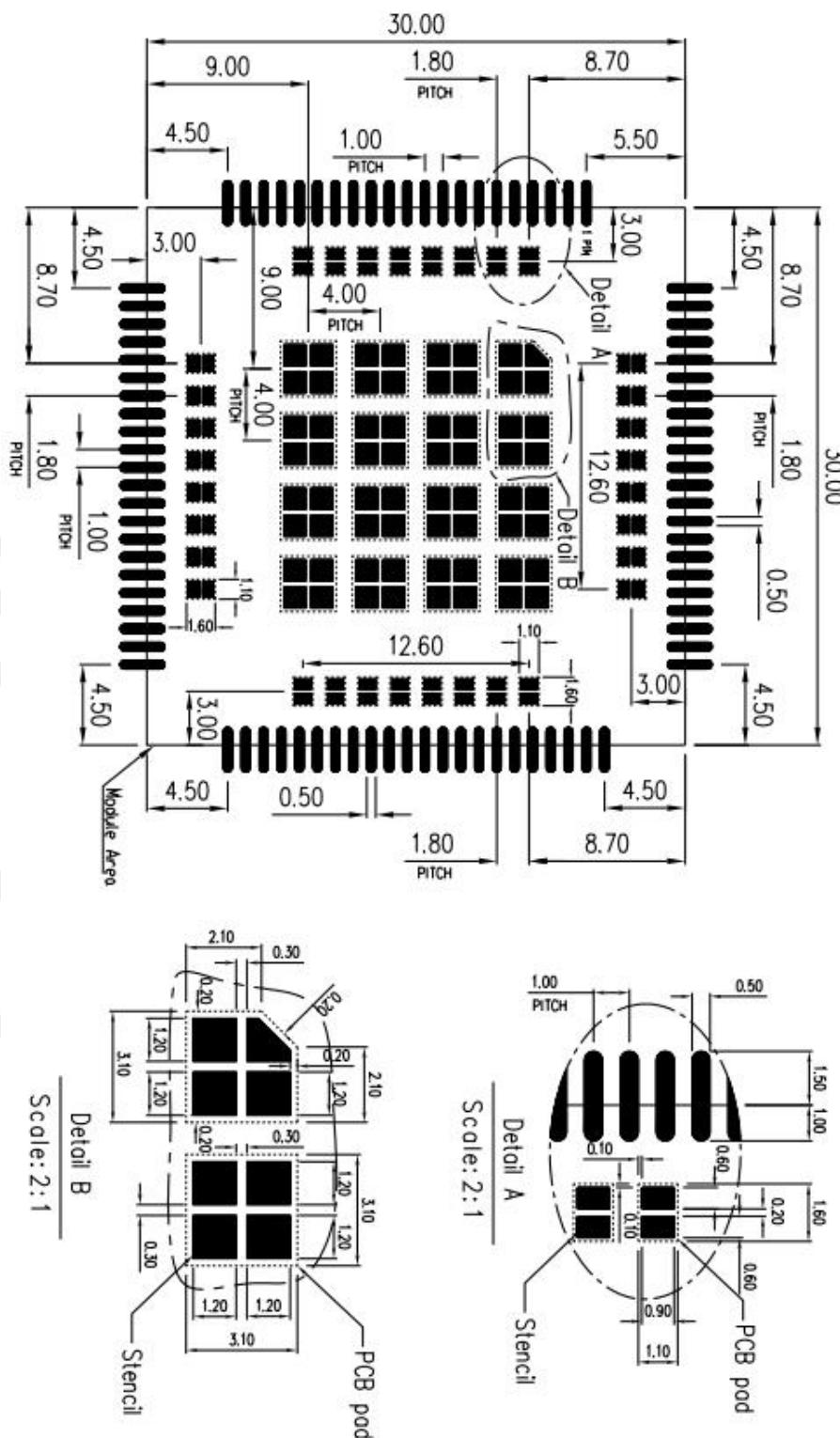

Figure 46: Stencil Foil

7. Packaging

Module support tray packaging.
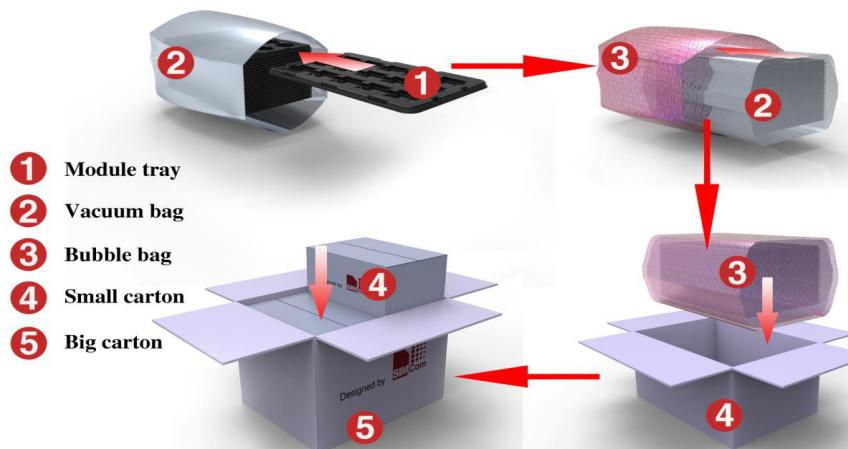
Figure 47: Packaging diagram

Module tray drawing：
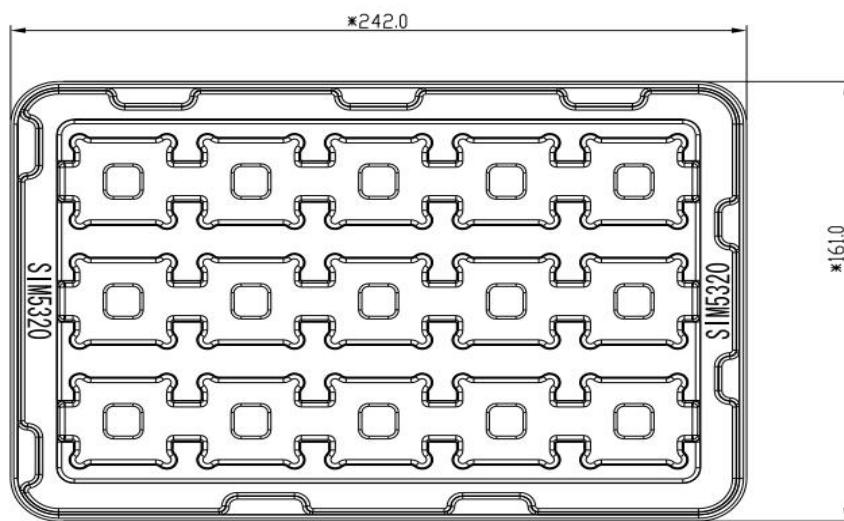
Figure 48: Tray drawing

Table 42: Tray size

Length（±3mm）	Width（±3mm）	Number
242.0	161.0	15

Small carton drawing：
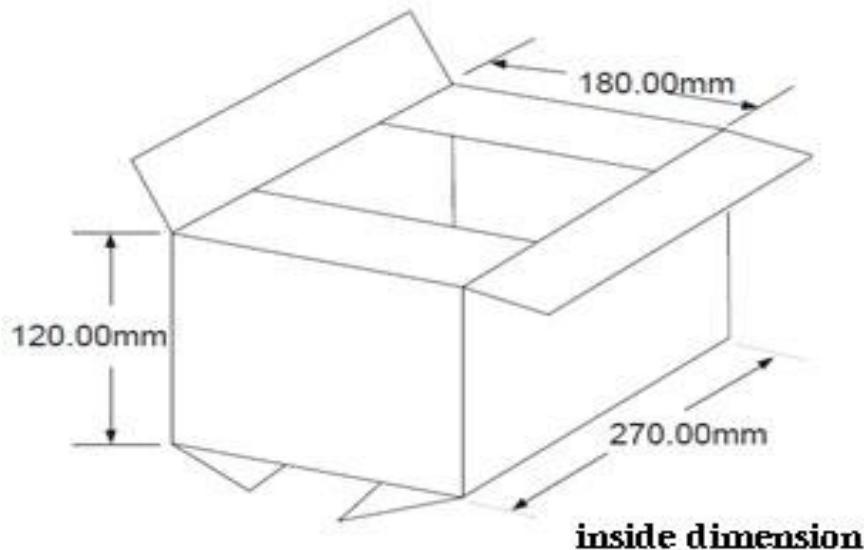
Figure 49: Small carton drawing

Table 43: Small carton size

Length（±10mm）	Width（±10mm）	Height（±10mm）	Number
270	180	120	15*20=300

Big carton drawing：
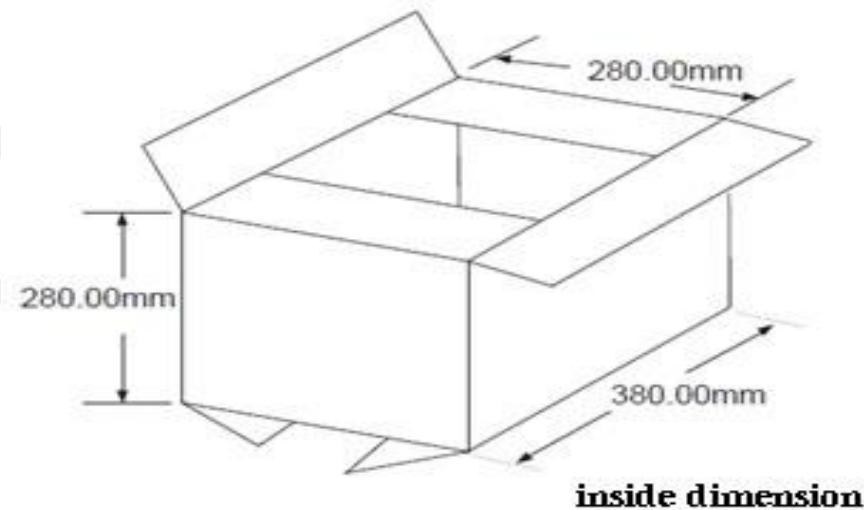
Figure 50: Big carton drawing

Table 44: Big carton size

Length（±10mm）	Width（±10mm）	Height（±10mm）	Number
380	280	280	300*4=1200

8. Appendix

8.1 Coding Schemes and Maximum Net Data Rates over Air Interface

Table 45: Coding schemes and maximum net data rates over air interface

Multislot definition(GPRS/EDGE)			
Slot class	DL slot number	UL slot number	Active slot number
1	1	1	2
2	2	1	3
3	2	2	3
4	3	1	4
5	2	2	4
6	3	2	4
7	3	3	4
8	4	1	5
9	3	2	5
10	4	2	5
11	4	3	5
12	4	4	5
GPRS coding scheme	**Max data rata（4 slots）**		**Modulation type**
CS 1 = 9.05 kb/s / time slot	36.2 kb/s		GMSK
CS 2 = 13.4 kb/s / time slot	53.6 kb/s		GMSK
CS 3 = 15.6 kb/s / time slot	62.4 kb/s		GMSK
CS 4 = 21.4 kb/s / time slot	85.6 kb/s		GMSK
EDGE coding scheme	**Max data rata（4 slots）**		**Modulation type**
MCS 1 = 8.8 kb/s/ time slot	35.2 kb/s		GMSK
MCS 2 = 11.2 kb/s/ time slot	44.8 kb/s		GMSK
MCS 3 = 14.8 kb/s/ time slot	59.2 kb/s		GMSK
MCS 4 = 17.6 kb/s/ time slot	70.4 kb/s		GMSK
MCS 5 = 22.4 kb/s/ time slot	89.6 kb/s		8PSK
MCS 6 = 29.6 kb/s/ time slot	118.4 kb/s		8PSK
MCS 7 = 44.8 kb/s/ time slot	179.2 kb/s		8PSK

MCS 8 = 54.4 kb/s/ time slot	217.6 kb/s	8PSK
MCS 9 = 59.2 kb/s/ time slot	236.8 kb/s	8PSK
HSDPA device category	**Max data rate（peak）**	**Modulation type**
Category 1	1.2Mbps	16QAM,QPSK
Category 2	1.2Mbps	16QAM,QPSK
Category 3	1.8Mbps	16QAM,QPSK
Category 4	1.8Mbps	16QAM,QPSK
Category 5	3.6Mbps	16QAM,QPSK
Category 6	3.6Mbps	16QAM,QPSK
Category 7	7.2Mbps	16QAM,QPSK
Category 8	7.2Mbps	16QAM,QPSK
Category 9	10.2Mbps	16QAM,QPSK
Category 10	14.4Mbps	16QAM,QPSK
Category 11	0.9Mbps	QPSK
Category 12	1.8Mbps	QPSK
Category 13	17.6Mbps	64QAM
Category 14	21.1Mbps	64QAM
Category 15	23.4Mbps	16QAM
Category 16	28Mbps	16QAM
Category 17	23.4Mbps	64QAM
Category 18	28Mbps	64QAM
Category 19	35.5Mbps	64QAM
Category 20	42Mbps	64QAM
Category 21	23.4Mbps	16QAM
Category 22	28Mbps	16QAM
Category 23	35.5Mbps	64QAM
Category 24	42.2Mbps	64QAM
HSUPA device category	**Max data rate（peak）**	**Modulation type**
Category 1	0.96Mbps	QPSK
Category 2	1.92Mbps	QPSK
Category 3	1.92Mbps	QPSK
Category 4	3.84Mbps	QPSK
Category 5	3.84Mbps	QPSK
Category 6	5.76Mbps	QPSK
LTE-FDD device category (Downlink)	**Max data rate（peak）**	**Modulation type**
Category 1	10Mbps	QPSK/16QAM/64QAM
Category 2	50Mbps	QPSK/16QAM/64QAM
Category 3	100Mbps	QPSK/16QAM/64QAM
Category 4	150Mbps	QPSK/16QAM/64QAM
LTE-FDD device category	**Max data rate（peak）**	**Modulation type**

(Uplink)		
Category 1	5Mbps	QPSK/16QAM
Category 2	25Mbps	QPSK/16QAM
Category 3	50Mbps	QPSK/16QAM
Category 4	50Mbps	QPSK/16QAM

8.2 Related Documents

Table 46: Related documents

NO.	Title	Description
[1]	SIM7500_SIM7600 Series_AT Command Manual_V1.xx	AT Command Manual
[2]	ITU-T Draft new recommendationV.25ter	Serial asynchronous automatic dialing and control
[3]	GSM 07.07	Digital cellular telecommunications (Phase 2+); AT command set for GSM Mobile Equipment (ME)
[4]	GSM 07.10	Support GSM 07.10 multiplexing protocol
[5]	GSM 07.05	Digital cellular telecommunications (Phase 2+); Use of Data Terminal Equipment – Data Circuit terminating Equipment (DTE – DCE) interface for Short Message Service (SMS) and Cell Broadcast Service (CBS)
[6]	GSM 11.14	Digital cellular telecommunications system (Phase 2+); Specification of the SIM Application Toolkit for the Subscriber Identity Module – Mobile Equipment (SIM – ME) interface
[7]	GSM 11.11	Digital cellular telecommunications system (Phase 2+); Specification of the Subscriber Identity Module – Mobile Equipment (SIM – ME) interface
[8]	GSM 03.38	Digital cellular telecommunications system (Phase 2+); Alphabets and language-specific information
[9]	GSM 11.10	Digital cellular telecommunications system (Phase 2)；Mobile Station (MS) conformance specification； Part 1: Conformance specification
[10]	3GPP TS 51.010-1	Digital cellular telecommunications system (Release 5); Mobile Station (MS) conformance specification
[11]	3GPP TS 34.124	Electromagnetic Compatibility (EMC) for mobile terminals and ancillary equipment.
[12]	3GPP TS 34.121	Electromagnetic Compatibility (EMC) for mobile terminals and ancillary equipment.
[13]	3GPP TS 34.123-1	Technical Specification Group Radio Access Network; Terminal conformance specification; Radio transmission and reception (FDD)
[14]	3GPP TS 34.123-3	User Equipment (UE) conformance specification; Part 3: Abstract Test Suites.
[15]	EN 301 908-02 V2.2.1	Electromagnetic compatibility and Radio spectrum Matters (ERM); Base Stations (BS) and User Equipment (UE) for IMT-2000. Third Generation cellular networks; Part 2: Harmonized EN for IMT-2000, CDMA Direct Spread

		(UTRA FDD) (UE) covering essential requirements of article 3.2 of the R&TTE Directive
[16]	EN 301 489-24 V1.2.1	Electromagnetic compatibility and Radio Spectrum Matters (ERM); Electromagnetic Compatibility (EMC) standard for radio equipment and services; Part 24: Specific conditions for IMT-2000 CDMA Direct Spread (UTRA) for Mobile and portable (UE) radio and ancillary equipment
[17]	IEC/EN60950-1(2001)	Safety of information technology equipment (2000)
[18]	3GPP TS 51.010-1	Digital cellular telecommunications system (Release 5); Mobile Station (MS) conformance specification
[19]	GCF-CC V3.23.1	Global Certification Forum - Certification Criteria
[20]	2002/95/EC	Directive of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS)
[21]	Module secondary-SMT-UGD-V1.xx	Module secondary SMT Guidelines
[22]	SIM7X00 Series_UART_Application Note_V1.xx	This document describes how to use UART interface of SIMCom modules.
[23]	SIM7100_SIM7500_SIM7600 Series_USB AUDIO_Application Note_V1.xx	USB AUDIO Application Note
[24]	SIM7X00 Series_GPS_Application Note_V1.xx	GPS Application Note
[25]	Antenna design guidelines for diversity receiver system	Antenna design guidelines for diversity receiver system
[26]	SIM7100_SIM7500_SIM7600_ Sleep Mode_Application Note_V1.xx	Sleep Mode Application Note
[27]	7600CE-LAN-Reference Design V1.0	HSIC Application Note
[28]	SIM7600_Series_SGMII-Reference_Design_V1.00	SGMII Reference Design

8.3 Terms and Abbreviations

Table 47: Terms and abbreviations

Abbreviation	Description
ADC	Analog-to-Digital Converter
ARP	Antenna Reference Point
BER	Bit Error Rate
BTS	Base Transceiver Station
CS	Coding Scheme
CSD	Circuit Switched Data
CTS	Clear to Send
DAC	Digital-to-Analog Converter
DRX	Discontinuous Reception
DSP	Digital Signal Processor
DTE	Data Terminal Equipment (typically computer, terminal, printer)
DTR	Data Terminal Ready
DTX	Discontinuous Transmission
EFR	Enhanced Full Rate
EGSM	Enhanced GSM
EMC	Electromagnetic Compatibility
ESD	Electrostatic Discharge
ETS	European Telecommunication Standard
EVDO	Evolution Data Only
FCC	Federal Communications Commission (U.S.)
FD	SIM fix dialing phonebook
FDMA	Frequency Division Multiple Access
FR	Full Rate
GMSK	Gaussian Minimum Shift Keying
GNSS	Global Navigation Satellite System
GPRS	General Packet Radio Service
GPS	Global Positioning System
GSM	Global Standard for Mobile Communications
HR	Half Rate
HSPA	High Speed Packet Access
I2C	Inter-Integrated Circuit
IMEI	International Mobile Equipment Identity
LTE	Long Term Evolution

MO	Mobile Originated
MS	Mobile Station (GSM engine), also referred to as TE
MT	Mobile Terminated
NMEA	National Marine Electronics Association
PAP	Password Authentication Protocol
PBCCH	Packet Switched Broadcast Control Channel
PCB	Printed Circuit Board
PCS	Personal Communication System, also referred to as GSM 1900
RF	Radio Frequency
RMS	Root Mean Square (value)
RTC	Real Time Clock
SIM	Subscriber Identification Module
SMS	Short Message Service
SPI	serial peripheral interface
SMPS	Switched-mode power supply
TDMA	Time Division Multiple Access
TE	Terminal Equipment, also referred to as DTE
TX	Transmit Direction
UART	Universal Asynchronous Receiver & Transmitter
VSWR	Voltage Standing Wave Ratio
SM	SIM phonebook
NC	Not connect
EDGE	Enhanced data rates for GSM evolution
HSDPA	High Speed Downlink Packet Access
HSUPA	High Speed Uplink Packet Access
ZIF	Zero intermediate frequency
WCDMA	Wideband Code Division Multiple Access
VCTCXO	Voltage control temperature-compensated crystal oscillator
USIM	Universal subscriber identity module
UMTS	Universal mobile telecommunications system
UART	Universal asynchronous receiver transmitter

8.4 Safety Caution

Table 48: Safety caution

Marks	Requirements
	When in a hospital or other health care facility, observe the restrictions about the use of mobiles. Switch the cellular terminal or mobile off, medical equipment may be sensitive and not operate normally due to RF energy interference.
	Switch off the cellular terminal or mobile before boarding an aircraft. Make sure it is switched off. The operation of wireless appliances in an aircraft is forbidden to prevent interference with communication systems. Forgetting to think much of these instructions may impact the flight safety, or offend local legal action, or both.
	Do not operate the cellular terminal or mobile in the presence of flammable gases or fumes. Switch off the cellular terminal when you are near petrol stations, fuel depots, chemical plants or where blasting operations are in progress. Operation of any electrical equipment in potentially explosive atmospheres can constitute a safety hazard.
	Your cellular terminal or mobile receives and transmits radio frequency energy while switched on. RF interference can occur if it is used close to TV sets, radios, computers or other electric equipment.
	Road safety comes first! Do not use a hand-held cellular terminal or mobile when driving a vehicle, unless it is securely mounted in a holder for hands free operation. Before making a call with a hand-held terminal or mobile, park the vehicle.
SOS	GSM cellular terminals or mobiles operate over radio frequency signals and cellular networks and cannot be guaranteed to connect in all conditions, especially with a mobile fee or an invalid SIM card. While you are in this condition and need emergent help, please remember to use emergency calls. In order to make or receive calls, the cellular terminal or mobile must be switched on and in a service area with adequate cellular signal strength. Some networks do not allow for emergency call if certain network services or phone features are in use (e.g. lock functions, fixed dialing etc.). You may have to deactivate those features before you can make an emergency call. Also, some networks require that a valid SIM card be properly inserted in the cellular terminal or mobile.